

# 3-Phase, Buck Controllers for AMD CPUs

## FEATURES

- 3-Phase Controller with Onboard MOSFET Drivers
- Current Mode Control Ensures Current Sharing
- Differential Amplifier Accurately Senses  $V_{OUT}$
- $\pm 5\%$  Output Current Matching Optimizes Thermal Performance and Size of Inductors and MOSFETs
- Reduced Input and Output Capacitance
- Supports Active Voltage Positioning
- VID Programmable Output Voltage from 0.8V to 1.55V (AMD Opteron™ CPU)
- 6-Phase, 90A to 120A Operation
- Output Power Good Indicator with Adaptive Blanking
- 210kHz to 530kHz Per Phase, PLL, Fixed Frequency
- Synchronizable (LTC3733-1)
- PWM, Stage Shedding or Burst Mode® Operation
- OPTI-LOOP® Compensation Minimizes  $C_{OUT}$
- Adjustable Soft-Start Current Ramping
- Short-Circuit Shutdown Timer with Defeat Option
- No\_CPU Detection
- 36-Lead 0.209" SSOP and 38-Lead (5mm × 7mm) QFN

## APPLICATIONS

- High Performance Notebook Computers
- Servers, Desktop Computers and Workstations

## DESCRIPTION

The LTC®3733 family are PolyPhase® synchronous step-down switching regulator controllers that drive all N-channel external power MOSFET stages in a phase-lockable, fixed frequency architecture. The 3-phase controller drives its output stages with 120° phase separation at frequencies of up to 530kHz per phase to minimize the RMS current dissipated by the ESR of both the input and output filter capacitors. The 3-phase technique effectively triples the fundamental frequency, improving transient response while operating each phase at an optimal frequency for efficiency and ease of thermal design. Light load efficiency is optimized by using a choice of output stage shedding or Burst Mode technology.

A differential amplifier provides true remote sensing of both the high and low sides of the output voltage at load points.

Soft-start and a defeatable, timed short-circuit shutdown protect the MOSFETs and the load. A foldback current circuit also provides protection for the external MOSFETs under short-circuit or overload conditions. An all-“1” VID detector turns off the regulator after 1μs timeout.

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## TYPICAL APPLICATION

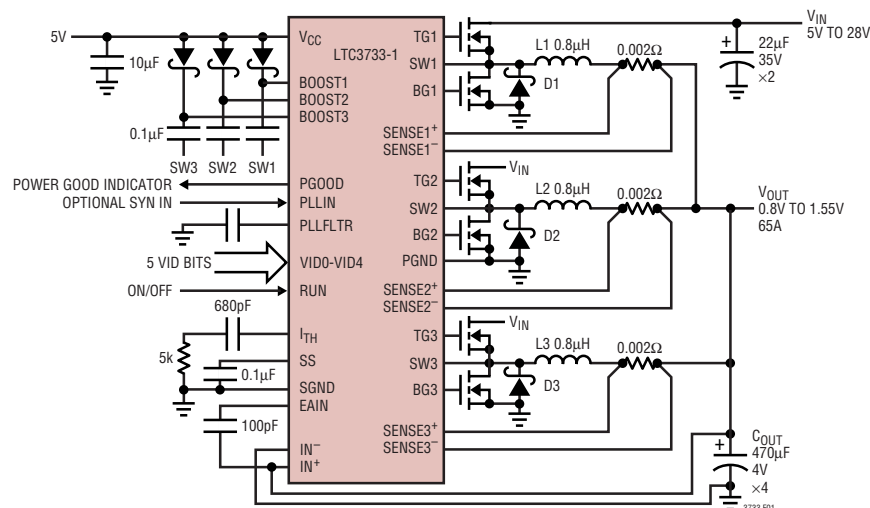


Figure 1. High Current Triple Phase Step-Down Converter

# LTC3733/LTC3733-1

## ABSOLUTE MAXIMUM RATINGS (Note 1)

|                                                                     |                          |                                           |                |
|---------------------------------------------------------------------|--------------------------|-------------------------------------------|----------------|
| Topside Driver Voltages (BOOST <sub>N</sub> ) .....                 | 38V to –0.3V             | I <sub>TH</sub> Voltage .....             | 2.4V to –0.3V  |
| Switch Voltage (SW <sub>N</sub> ) .....                             | 32V to –5V               | Operating Ambient Temperature Range ..... | 0°C to 70°C    |
| Boosted Driver Voltage (BOOST <sub>N</sub> – SW <sub>N</sub> ) .... | 7V to –0.3V              | Junction Temperature (Note 2) .....       | 125°C          |
| Peak Output Current <1ms (TG <sub>N</sub> , BG <sub>N</sub> ) ..... | 5A                       | Storage Temperature Range                 |                |
| Supply Voltage (V <sub>CC</sub> ), PG00D                            |                          | LTC3733CG .....                           | –65°C to 150°C |
| Pin Voltages .....                                                  | 7V to –0.3V              | LTC3733CUHF-1 .....                       | –65°C to 125°C |
| PLLIN, RUN, SS,                                                     |                          | Lead Temperature (LTC3733CG)              |                |
| PLLFLTR, FCB Voltages .....                                         | V <sub>CC</sub> to –0.3V | (Soldering, 10 sec) .....                 | 300°C          |

## PACKAGE/ORDER INFORMATION

|                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |                                           |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |                                                                                    |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------|
| <p>TOP VIEW</p> <p>VID1 [1] 36 VID0<br/>         RUN [2] 35 PG00D<br/>         PLLFLTR [3] 34 BOOST1<br/>         FCB [4] 33 TG1<br/>         IN<sup>+</sup> [5] 32 SW1<br/>         IN<sup>–</sup> [6] 31 BOOST2<br/>         DIFFOUT [7] 30 TG2<br/>         EAIN [8] 29 SW2<br/>         SGND [9] 28 V<sub>CC</sub><br/>         SENSE1<sup>+</sup> [10] 27 BG1<br/>         SENSE1<sup>–</sup> [11] 26 PGND<br/>         SENSE2<sup>+</sup> [12] 25 BG2<br/>         SENSE2<sup>–</sup> [13] 24 BG3<br/>         SENSE3<sup>–</sup> [14] 23 SW3<br/>         SENSE3<sup>+</sup> [15] 22 TG3<br/>         SS [16] 21 BOOST3<br/>         I<sub>TH</sub> [17] 20 VID4<br/>         VID2 [18] 19 VID3</p> <p>G PACKAGE<br/>         36-LEAD PLASTIC SSOP<br/>         T<sub>JMAX</sub> = 125°C, θ<sub>JA</sub> = 95°C/W</p> | <p>ORDER PART NUMBER</p> <p>LTC3733CG</p> | <p>TOP VIEW</p> <p>PLLFLTR [1] 38<br/>         FCB [2] 37<br/>         IN<sup>+</sup> [3] 36<br/>         IN<sup>–</sup> [4] 35<br/>         DIFFOUT [5] 34<br/>         EAIN [6] 33<br/>         SGND [7] 32<br/>         SENSE1<sup>+</sup> [8] 31<br/>         SENSE1<sup>–</sup> [9] 30<br/>         SENSE2<sup>+</sup> [10] 29<br/>         SENSE2<sup>–</sup> [11] 28<br/>         SENSE3<sup>–</sup> [12] 27<br/>         SENSE3<sup>+</sup> [13] 26<br/>         SS [14] 25<br/>         I<sub>TH</sub> [15] 24<br/>         VID2 [16] 23<br/>         VID3 [17] 22<br/>         VID4 [18] 21<br/>         BOOST3 [19] 20</p> <p>UHF PACKAGE<br/>         38-LEAD (7mm × 5mm) PLASTIC QFN<br/>         T<sub>JMAX</sub> = 125°C, θ<sub>JA</sub> = 34°C/W<br/>         EXPOSED PAD IS SGND (PIN 39) MUST BE SOLDERED TO PCB</p> | <p>ORDER PART NUMBER</p> <p>LTC3733CUHF-1</p> <p>UHF PART MARKING</p> <p>37331</p> |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------|

Consult LTC Marketing for parts specified with wider operating temperature ranges.

## ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T<sub>A</sub> = 25°C. V<sub>CC</sub> = V<sub>RUN</sub> = V<sub>SS</sub> = 5V unless otherwise noted.

| SYMBOL                   | PARAMETER                            | CONDITIONS                                                                                                                                                                       | MIN              | TYP            | MAX            | UNITS    |
|--------------------------|--------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------|----------------|----------------|----------|
| <b>Main Control Loop</b> |                                      |                                                                                                                                                                                  |                  |                |                |          |
| V <sub>REGULATED</sub>   | Regulated Voltage at IN <sup>+</sup> | (Note 3); VID Code = 10011, V <sub>I<sub>TH</sub></sub> = 1.2V                                                                                                                   | ● 1.067<br>1.064 | 1.075<br>1.075 | 1.083<br>1.086 | V<br>V   |
| V <sub>SENSEMAX</sub>    | Maximum Current Sense Threshold      | V <sub>EAIN</sub> = 0.5V, V <sub>I<sub>TH</sub></sub> Open,<br>V <sub>SENSE1<sup>–</sup></sub> , V <sub>SENSE2<sup>–</sup></sub> , V <sub>SENSE3<sup>–</sup></sub> = 0.8V, 1.55V | ● 65<br>62       | 75<br>75       | 85<br>88       | mV<br>mV |
| I <sub>MATCH</sub>       | Current Match                        | Worst-Case Error at V <sub>SENSE(MAX)</sub>                                                                                                                                      | –5               |                | 5              | %        |

3733f

# ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ .  $V_{CC} = V_{RUN} = V_{SS} = 5\text{V}$  unless otherwise noted.

| SYMBOL                             | PARAMETER                                                                | CONDITIONS                                                                                                                                                               |        | MIN                   | TYP                   | MAX                   | UNITS    |
|------------------------------------|--------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|-----------------------|-----------------------|-----------------------|----------|
| V <sub>LOADREG</sub>               | Output Voltage Load Regulation                                           | (Note 3)<br>Measured in Servo Loop, ΔI <sub>TH</sub> Voltage = 1.2V to 0.7V<br>Measured in Servo Loop, ΔI <sub>TH</sub> Voltage = 1.2V to 2V                             | ●<br>● |                       | 0.1<br>−0.1           | 0.5<br>−0.5           | %<br>%   |
| V <sub>REFLNREG</sub>              | Output Voltage Line Regulation                                           | V <sub>CC</sub> = 4.5V to 7V                                                                                                                                             |        |                       | 0.03                  |                       | %/V      |
| g <sub>m</sub>                     | Transconductance Amplifier g <sub>m</sub>                                | I <sub>TH</sub> = 1.2V, Sink/Source 25μA (Note 3)                                                                                                                        |        | 2.5                   | 3.05                  | 3.6                   | mmho     |
| g <sub>mOL</sub>                   | Transconductance Amplifier GBW                                           | I <sub>TH</sub> = 1.2V, (g <sub>m</sub> • Z <sub>L</sub> , Z <sub>L</sub> = Series 1k-100kΩ-1nF)                                                                         |        |                       | 1.5                   |                       | MHz      |
| V <sub>FCB</sub>                   | Forced Continuous Threshold                                              |                                                                                                                                                                          | ●      | 0.58                  | 0.60                  | 0.62                  | V        |
| I <sub>FCB</sub>                   | FCB Bias Current                                                         | V <sub>FCB</sub> = 0.65V                                                                                                                                                 |        |                       | 0.2                   | 0.7                   | μA       |
| V <sub>BINHIBIT</sub>              | Burst Inhibit Threshold                                                  | Measured at FCB pin                                                                                                                                                      |        | V <sub>CC</sub> − 1.5 | V <sub>CC</sub> − 0.7 | V <sub>CC</sub> − 0.3 | V        |
| UVR                                | Undervoltage SS Reset                                                    | V <sub>CC</sub> Lowered Until the SS Pin is Pulled Low                                                                                                                   |        | 3.3                   | 3.8                   | 4.5                   | V        |
| I <sub>Q</sub>                     | Input DC Supply Current<br>Normal Mode<br>Shutdown                       | (Note 4)<br>V <sub>CC</sub> = 5V<br>V <sub>RUN</sub> = 0V, VID0 to VID4 Open                                                                                             |        |                       | 2.5<br>20             |                       | mA<br>μA |
| V <sub>RUN</sub>                   | RUN Pin ON Threshold                                                     | V <sub>RUN</sub> , Ramping Positive                                                                                                                                      |        | 1                     | 1.5                   | 1.9                   | V        |
| I <sub>SS</sub>                    | Soft-Start Charge Current                                                | V <sub>SS</sub> = 1.9V                                                                                                                                                   |        | −0.8                  | −1.5                  | −2.5                  | μA       |
| V <sub>SSARM</sub>                 | SS Pin Arming Threshold                                                  | V <sub>SS</sub> , Ramping Positive Until Short-Circuit Latch-Off is Armed                                                                                                |        |                       | 3.8                   | 4.5                   | V        |
| V <sub>SSLO</sub>                  | SS Pin Latch-Off Threshold                                               | V <sub>SS</sub> , Ramping Negative                                                                                                                                       |        |                       | 3.3                   |                       | V        |
| I <sub>SCL</sub>                   | SS Discharge Current                                                     | Soft-Short Condition V <sub>EAIN</sub> = 0.375V, V <sub>SS</sub> = 4.5V                                                                                                  |        | −5                    | −1.5                  |                       | μA       |
| I <sub>SDLHO</sub>                 | Shutdown Latch Disable Current                                           | V <sub>EAIN</sub> = 0.375V, V <sub>SS</sub> = 4.5V                                                                                                                       |        |                       | 1.5                   | 5                     | μA       |
| I <sub>SENSE</sub>                 | SENSE Pins Source Current                                                | SENSE1 <sup>+</sup> , SENSE1 <sup>−</sup> , SENSE2 <sup>+</sup> , SENSE2 <sup>−</sup> ,<br>SENSE3 <sup>+</sup> , SENSE3 <sup>−</sup> All Equal 1.2V; Current at Each Pin |        |                       | 13                    | 20                    | μA       |
| DF <sub>MAX</sub>                  | Maximum Duty Factor                                                      | In Dropout                                                                                                                                                               |        | 95                    | 98.5                  |                       | %        |
| TG t <sub>R</sub> , t <sub>F</sub> | Top Gate Rise Time<br>Top Gate Fall Time                                 | C <sub>LOAD</sub> = 3300pF<br>C <sub>LOAD</sub> = 3300pF                                                                                                                 |        |                       | 30<br>40              | 90<br>90              | ns<br>ns |
| BG t <sub>R</sub> , t <sub>F</sub> | Bottom Gate Rise Time<br>Bottom Gate Fall Time                           | C <sub>LOAD</sub> = 3300pF<br>C <sub>LOAD</sub> = 3300pF                                                                                                                 |        |                       | 30<br>20              | 90<br>90              | ns<br>ns |
| TG/BG t <sub>1D</sub>              | Top Gate Off to Bottom Gate On Delay<br>Synchronous Switch-On Delay Time | All Controllers, C <sub>LOAD</sub> = 3300pF Each Driver                                                                                                                  |        |                       | 60                    |                       | ns       |
| BG/TG t <sub>2D</sub>              | Bottom Gate Off to Top Gate On Delay<br>Top Switch-On Delay Time         | All Controllers, C <sub>LOAD</sub> = 3300pF Each Driver                                                                                                                  |        |                       | 60                    |                       | ns       |
| t <sub>ON(MIN)</sub>               | Minimum On-Time                                                          | Tested with a Square Wave (Note 5)                                                                                                                                       |        |                       | 120                   |                       | ns       |

## VID Parameters

|                       |                                          |          |   |       |      |            |
|-----------------------|------------------------------------------|----------|---|-------|------|------------|
| VID <sub>IL</sub>     | Maximum Low Level Input Voltage          |          |   |       | 0.8  | V          |
| VID <sub>IH</sub>     | Minimum High Level Input Voltage         |          | 2 |       |      | V          |
| VID <sub>PULLUP</sub> | VID0 to VID4 Internal Pull-Up Resistance |          |   | 150   |      | k $\Omega$ |
| ATTEN <sub>ERR</sub>  | VID0 to VID4                             | (Note 6) | ● | -0.25 | 0.25 | %          |

## Power Good Output Indication

|                                              |                                                                                                        |                                                                                                                               |  |         |           |                     |
|----------------------------------------------|--------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------|--|---------|-----------|---------------------|
| V <sub>PGL</sub>                             | PGOOD Voltage Output Low                                                                               | I <sub>PGOOD</sub> = 2mA                                                                                                      |  | 0.1     | 0.3       | V                   |
| I <sub>PGOOD</sub>                           | PGOOD Output Leakage                                                                                   | V <sub>PGOOD</sub> = 5V                                                                                                       |  |         | ±1        | μA                  |
| V <sub>PGTHNEG</sub><br>V <sub>PGTHPOS</sub> | PGOOD Trip Thesholds<br>V <sub>DIFFOUT</sub> Ramping Negative<br>V <sub>DIFFOUT</sub> Ramping Positive | V <sub>DIFFOUT</sub> with Respect to Set Output Voltage,<br>VID Code = 10011<br>PGOOD Goes Low After V <sub>UVDLY</sub> Delay |  | −7<br>7 | −10<br>10 | −14<br>14<br>%<br>% |
| t <sub>PGBLNK</sub>                          | Power Good Blanking                                                                                    | After VID Changes Outside PGOOD Window                                                                                        |  | 120     |           | μs                  |

# ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ .  $V_{CC} = V_{RUN} = V_{SS} = 5\text{V}$  unless otherwise noted.

| SYMBOL                                  | PARAMETER                                                                  | CONDITIONS                                                                                   | MIN            | TYP            | MAX   | UNITS                          |
|-----------------------------------------|----------------------------------------------------------------------------|----------------------------------------------------------------------------------------------|----------------|----------------|-------|--------------------------------|
| <b>Oscillator and Phase-Locked Loop</b> |                                                                            |                                                                                              |                |                |       |                                |
| $f_{\text{NOM}}$                        | Nominal Frequency                                                          | $V_{\text{PLLFLTR}} = 1.2\text{V}$                                                           | 310            | 350            | 400   | kHz                            |
| $f_{\text{LOW}}$                        | Lowest Frequency                                                           | $V_{\text{PLLFLTR}} = 0\text{V}$                                                             | 190            | 210            | 250   | kHz                            |
| $f_{\text{HIGH}}$                       | Highest Frequency                                                          | $V_{\text{PLLFLTR}} = 2.4\text{V}$                                                           | 470            | 530            | 620   | kHz                            |
| $R_{\text{PLLTH}}$                      | PLLIN Input Threshold                                                      | LTC3733-1 Only                                                                               |                | 1              |       | V                              |
| $R_{\text{PLL IN}}$                     | PLLIN Input Resistance                                                     | LTC3733-1 Only                                                                               |                | 50             |       | k $\Omega$                     |
| $I_{\text{PLL LPF}}$                    | Phase Detector Output Current<br>Sinking Capability<br>Sourcing Capability | LTC3733-1 Only<br>$f_{\text{PLLIN}} < f_{\text{OSC}}$<br>$f_{\text{PLLIN}} > f_{\text{OSC}}$ |                | 20<br>20       |       | $\mu\text{A}$<br>$\mu\text{A}$ |
| $R_{\text{RELPHS}}$                     | Controller 2-Controller 1 Phase<br>Controller 3-Controller 1 Phase         |                                                                                              |                | 120<br>240     |       | Deg<br>Deg                     |
| <b>No_CPU Detection</b>                 |                                                                            |                                                                                              |                |                |       |                                |
| $t_{\text{NOCPU}}$                      | No-CPU Shutdown Latency                                                    | After All VID Bits = "1"                                                                     | 0.5            | 1              |       | $\mu\text{s}$                  |
| <b>Differential Amplifier</b>           |                                                                            |                                                                                              |                |                |       |                                |
| $A_V$                                   | Differential Gain                                                          |                                                                                              | 0.995          | 1.000          | 1.005 | V/V                            |
| $V_{\text{OS}}$                         | Input Offset Voltage                                                       | $IN^+ = IN^- = 1.2\text{V}$ , $I_{\text{OUT}} = 1\text{mA}$ ,<br>Input Referred; Gain = 1    |                | 0.5            | 5     | mV                             |
| CM                                      | Common Mode Input Voltage Range                                            |                                                                                              | 0              |                | 5     | V                              |
| CMRR                                    | Common Mode Rejection Ratio                                                | $0\text{V} < IN^+ = IN^- < 5\text{V}$ , $I_{\text{OUT}} = 1\text{mA}$ , Input Referred       | 50             | 70             |       | dB                             |
| $I_{\text{CL}}$                         | Output Current                                                             |                                                                                              | 10             | 40             |       | mA                             |
| GBP                                     | Gain Bandwidth Product                                                     |                                                                                              |                | 2              |       | MHz                            |
| SR                                      | Slew Rate                                                                  | $R_L = 2\text{k}$                                                                            |                | 5              |       | V/ $\mu\text{s}$               |
| $V_{\text{O(MAX)}}$                     | Maximum High Output Voltage                                                | $I_{\text{OUT}} = 1\text{mA}$                                                                | $V_{CC} - 1.2$ | $V_{CC} - 0.8$ |       | V                              |
| $R_{\text{IN}}$                         | Input Resistance                                                           | Measured at $IN^+$ Pin                                                                       |                | 80             |       | k $\Omega$                     |

**Note 1:** Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2:**  $T_J$  is calculated from the ambient temperature  $T_A$  and power dissipation  $P_D$  according to the following formula:

$$\text{LTC3733CG: } T_J = T_A + (P_D \times 95^\circ\text{C/W})$$

$$\text{LTC3733CUHF-1: } T_J = T_A + (P_D \times 34^\circ\text{C/W})$$

**Note 3:** The IC is tested in a feedback loop that includes the differential amplifier in a unity-gain configuration loaded with  $100\mu\text{A}$  to ground driving the VID DAC into the error amplifier and servoing the resultant voltage to the midrange point for the error amplifier ( $V_{\text{ITH}} = 1.2\text{V}$ ).

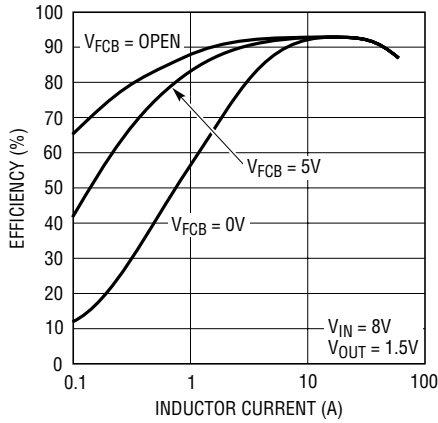
**Note 4:** Dynamic supply current is higher due to the gate charge being delivered at the switching frequency. See Applications Information.

**Note 5:** The minimum on-time condition corresponds to an inductor peak-to-peak ripple current of  $\geq 40\%$  of  $I_{\text{MAX}}$  (see minimum on-time considerations in the Applications Information Section).

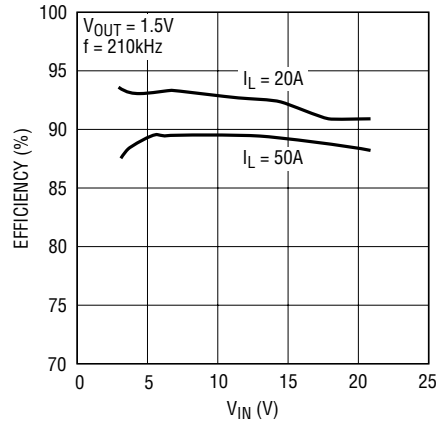
**Note 6:**  $\text{ATTEN}_{\text{ERR}}$  specification is in addition to the output voltage accuracy specified at VID code 10011.

**Note 7:** This IC includes overtemperature protection that is intended to protect the device during momentary overload conditions. Junction temperature will exceed  $125^\circ\text{C}$  when overtemperature protection is active. Continuous operation above the specified maximum operating junction temperature may impair device reliability.

## TYPICAL PERFORMANCE CHARACTERISTICS

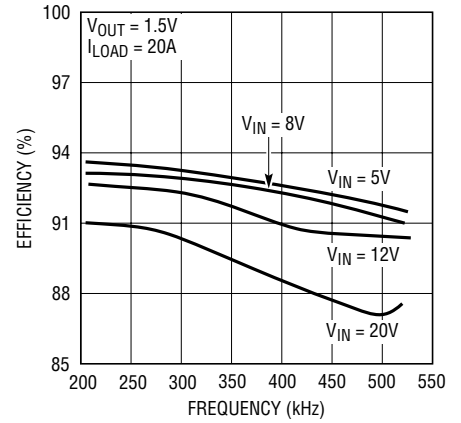
Efficiency vs  $I_{OUT}$ 

3733 G01

Efficiency vs  $V_{IN}$ 

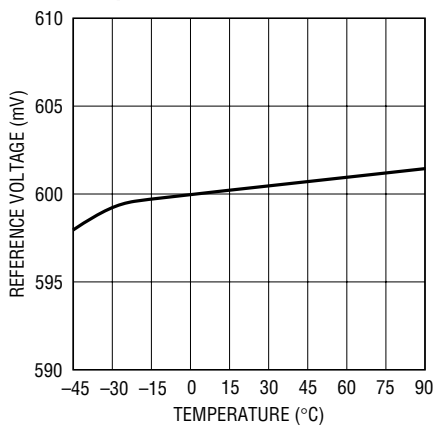
3733 G02

Efficiency vs Frequency

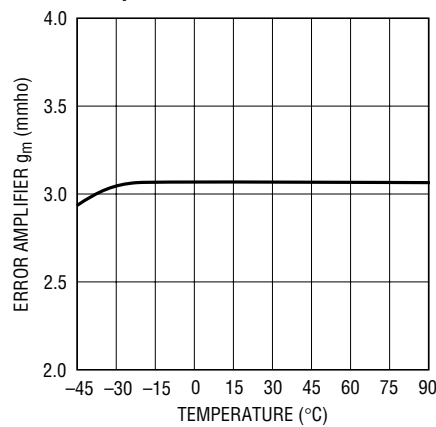


3733 G03

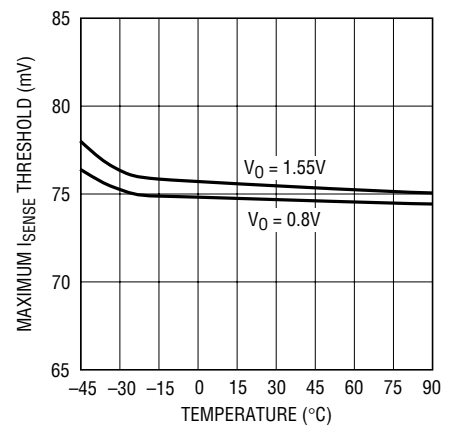
Reference Voltage vs Temperature



3733 G04

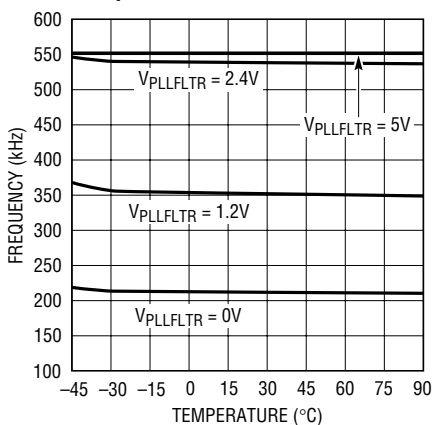
Error Amplifier  $g_m$  vs Temperature

3733 G05

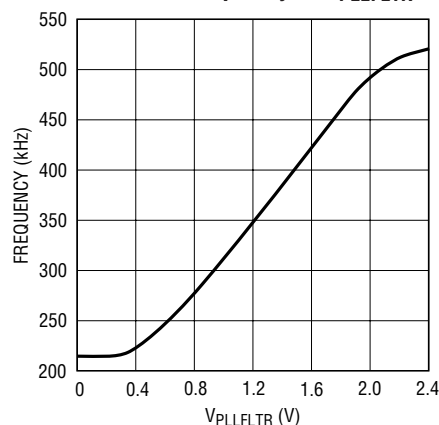
Maximum  $I_{SENSE}$  Threshold vs Temperature

3733 G06

Oscillator Frequency vs Temperature

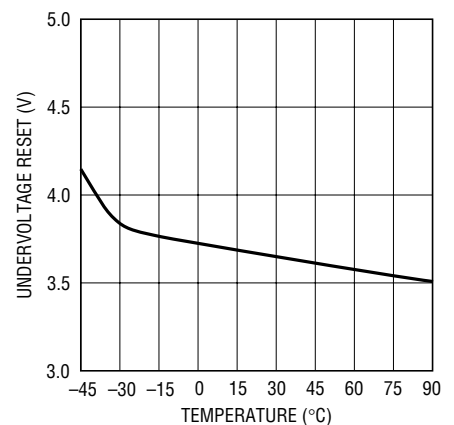


3733 G07

Oscillator Frequency vs  $V_{PLLFLTR}$ 

3733 G08

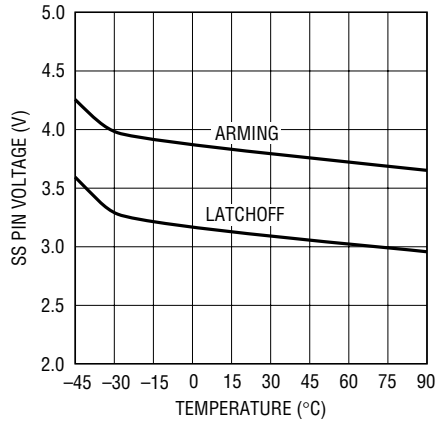
Undervoltage Reset Voltage vs Temperature



3733 G09

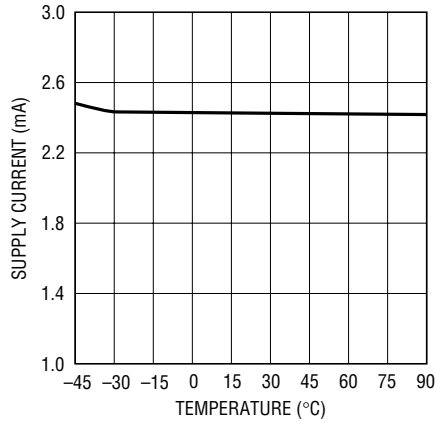
## TYPICAL PERFORMANCE CHARACTERISTICS

Short-Circuit Arming and Latchoff vs Temperature



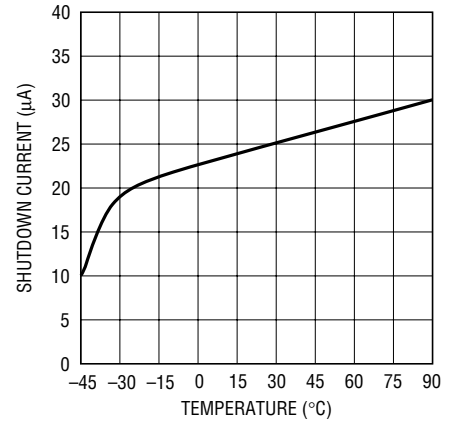
3733 G10

Supply Current vs Temperature



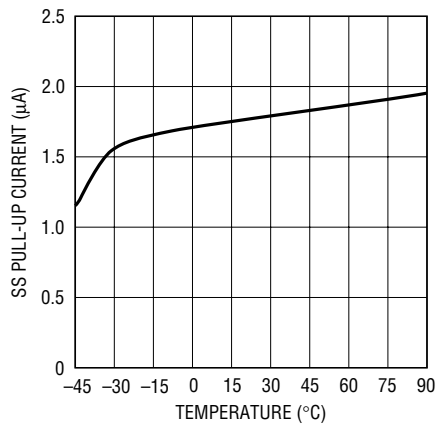
3733 G11

Shutdown Current vs Temperature



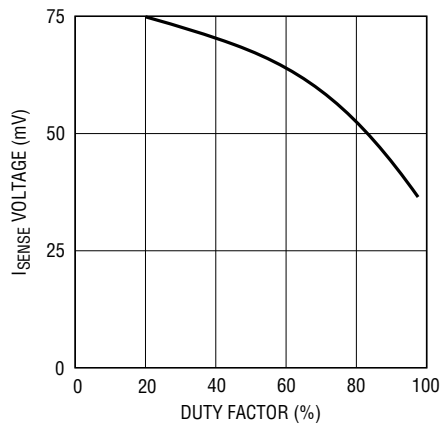
3733 G12

SS Pull-Up Current vs Temperature

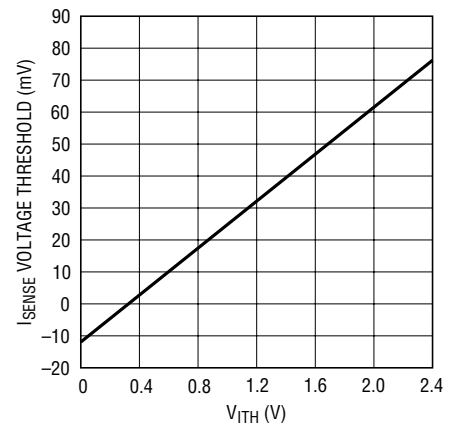


3733 G13

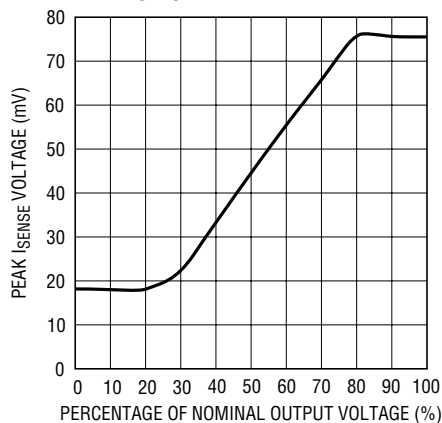
Maximum Current Sense Threshold vs Duty Factor



3733 G14

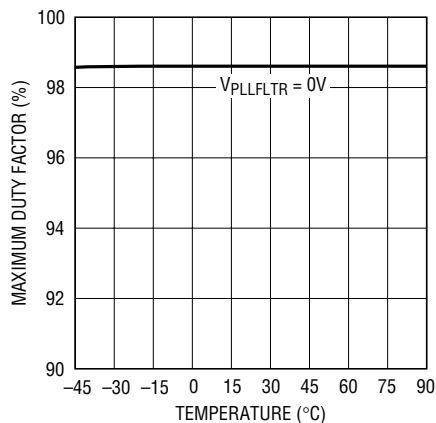
Peak Current Threshold vs V<sub>ITH</sub>

3733 G15

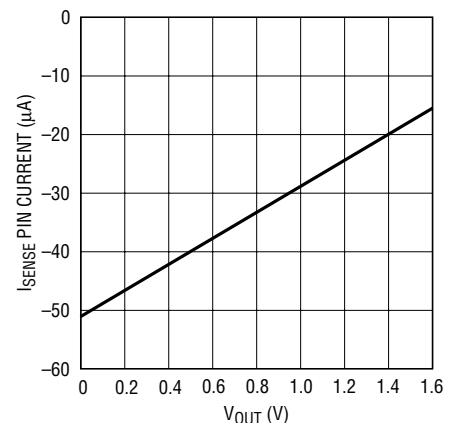
Percentage of Nominal Output vs Peak I<sub>SENSE</sub> (Foldback)

3733 G16

Maximum Duty Factors vs Temperature



3733 G17

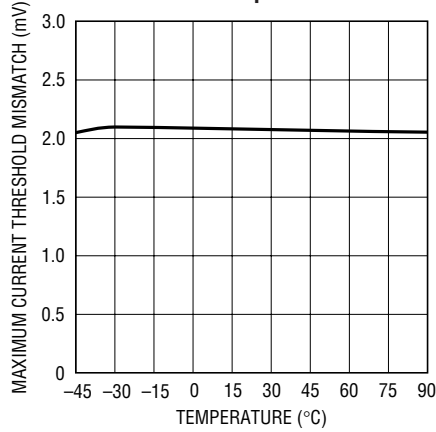
I<sub>SENSE</sub> Pin Current vs V<sub>OUT</sub>

3733 G18

3733f

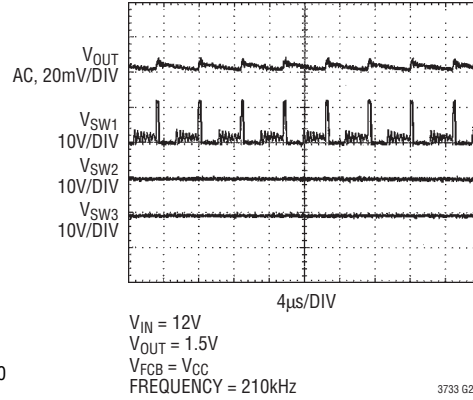
# TYPICAL PERFORMANCE CHARACTERISTICS

**Maximum Current Threshold Mismatch vs Temperature**



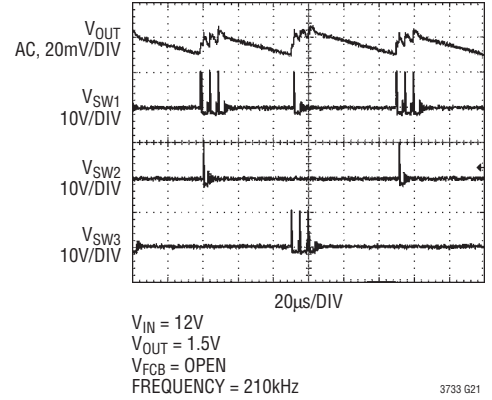
3733 G19

**Shed Mode at 1Amp, Light Load Current**



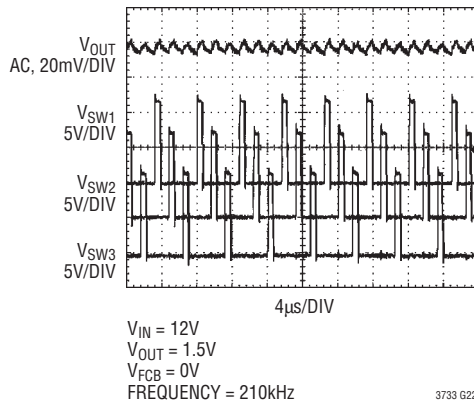
3733 G20

**Burst Mode at 1Amp, Light Load Current**



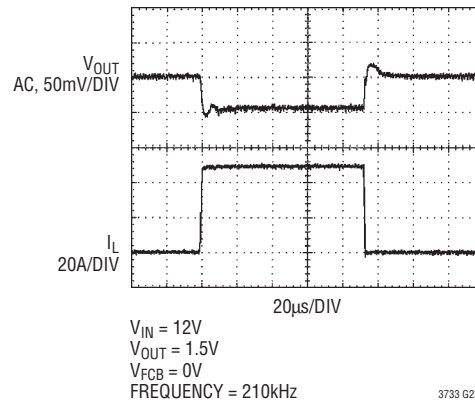
3733 G21

**Continuous Mode at 1Amp, Light Load Current**



3733 G22

**Transient Load Current Response: 0Amp to 50Amp**



3733 G23

## PIN FUNCTIONS (G36/QFN)

**VID0 to VID4 (Pins 36, 1, 18, 19, 20/Pins 35, 36, 16, 17, 18):** Output Voltage Programming Input Pins. A 150k internal pull-up resistor is provided on each input pin. See Table 1 for details. Do not apply voltage to these pins prior to the application of voltage on the  $V_{CC}$  pin.

**RUN (Pin 2/Pin 37):** ON/OFF Control of the LTC3733.

**PLLFLTR (Pin 3/Pin 1):** The phase-locked loop's lowpass filter is tied to this pin. Alternatively, this pin can be driven with an AC or DC voltage source to vary the frequency of the internal oscillator. (Do not apply voltage to this pin prior to the application of voltage on the  $V_{CC}$  pin.)

**FCB (Pin 4/Pin 2):** Forced Continuous Control Input. The voltage applied to this pin sets the operating mode of the controller. The forced continuous current mode is active when the applied voltage is less than 0.6V. Burst Mode operation will be active when the pin is allowed to float and a stage shedding mode will be active if the pin is tied to the  $V_{CC}$  pin. (Do not apply voltage to this pin prior to the application of voltage on the  $V_{CC}$  pin.)

**IN<sup>+</sup>, IN<sup>-</sup> (Pins 5, 6/Pins 3, 4):** Inputs to a precision, unity-gain differential amplifier with internal precision resistors. This provides true remote sensing of both the positive and negative load terminals for precise output voltage control.

**DIFFOUT (Pin 7/Pin 5):** Output of the Remote Output Voltage Sensing Differential Amplifier.

**EAIN (Pin 8/Pin 6):** This is the input to the error amplifier which compares the VID divided, feedback voltage to the internal 0.6V reference voltage.

**SGND (Pin 9/Pin 7, 39):** Signal Ground. This pin must be routed separately under the IC to the PGND pin and then to the main ground plane. The exposed pad (QFN) must be soldered to the PCB for optimal thermal performance.

**SENSE1<sup>+</sup>, SENSE2<sup>+</sup>, SENSE3<sup>+</sup>, SENSE1<sup>-</sup>, SENSE2<sup>-</sup>, SENSE3<sup>-</sup> (Pins 10 to 15/Pins 8 to 13):** The Inputs to Each Differential Current Comparator. The  $I_{TH}$  pin voltage and built-in offsets between SENSE<sup>-</sup> and SENSE<sup>+</sup> pins, in conjunction with  $R_{SENSE}$ , set the current trip threshold level.

**SS (Pin 16/Pin 14):** Combination of Soft-Start and Short-Circuit Detection Timer. A capacitor to ground at this pin sets the ramp time to full current output as well as the time delay prior to an output voltage short-circuit shutdown. A minimum value of 0.01 $\mu$ F is recommended on this pin.

**$I_{TH}$  (Pin 17/Pin 15):** Error Amplifier Output and Switching Regulator Compensation Point. All three current comparator's thresholds increase with this control voltage.

**PGND (Pin 26/Pin 24):** Driver Power Ground. This pin connects to the sources of the bottom N-channel external MOSFETs and the (-) terminals of  $C_{IN}$ .

**BG1 to BG3 (Pins 27, 25, 24/Pins 25, 23, 22):** High Current Gate Drives for Bottom N-Channel MOSFETs. Voltage swing at these pins is from ground to  $V_{CC}$ .

**DRV<sub>CC</sub> (NA/Pin 26):** High Power Supply to Drive the External MOSFET Gates in QFN Package. This pin needs to be closely decoupled to the IC's PGND pin.

**$V_{CC}$  (Pin 28/Pin 27):** Main Supply Pin. This pin supplies the controller circuit power. In the G36 package, it is also the high power supply to drive the external MOSFET gates and this pin needs to be closely decoupled to the IC's PGND pin.

**SW1 to SW3 (Pins 32, 29, 23/Pins 31, 28, 21):** Switch Node Connections to Inductors. Voltage swing at these pins is from a Schottky diode (external) voltage drop below ground to  $V_{IN}$  (where  $V_{IN}$  is the external MOSFET supply rail).

## PIN FUNCTIONS (G36/QFN)

**TG1 to TG3 (Pins 33, 30, 22/Pins 32, 29, 20):** High Current Gate Drives for Top N-channel MOSFETs. These are the outputs of floating drivers with a voltage swing equal to the boost voltage source superimposed on the switch node voltage SW.

**BOOST1 to BOOST3 (Pins 34, 31, 21/Pins 33, 30, 19):** Positive Supply Pins to the Topside Floating Drivers. Bootstrapped capacitors, charged with external Schottky diodes and a boost voltage source, are connected between the BOOST and SW pins. Voltage swing at the BOOST pins is from boost source voltage (typically  $V_{CC}$ ) to this boost source voltage +  $V_{IN}$  (where  $V_{IN}$  is the external MOSFET supply rail).

**PGOOD (Pin 35/Pin 34):** This open-drain output is pulled low when the output voltage is outside the PGOOD tolerance window. PGOOD is blanked during VID transitions for approximately 120 $\mu$ s.

**PLLIN (NA/Pin 38):** Synchronization Input to Phase Detector. This pin is internally terminated to SGND with 50k $\Omega$ . The phase-locked loop will force the rising top gate signal of controller 1 to be synchronized with the rising edge of the PLLIN signal. This pin is not available in the G36 package.

**Exposed Pad (NA/Pin 39):** Signal Ground. Must be soldered to PCB.

## FUNCTIONAL DIAGRAM

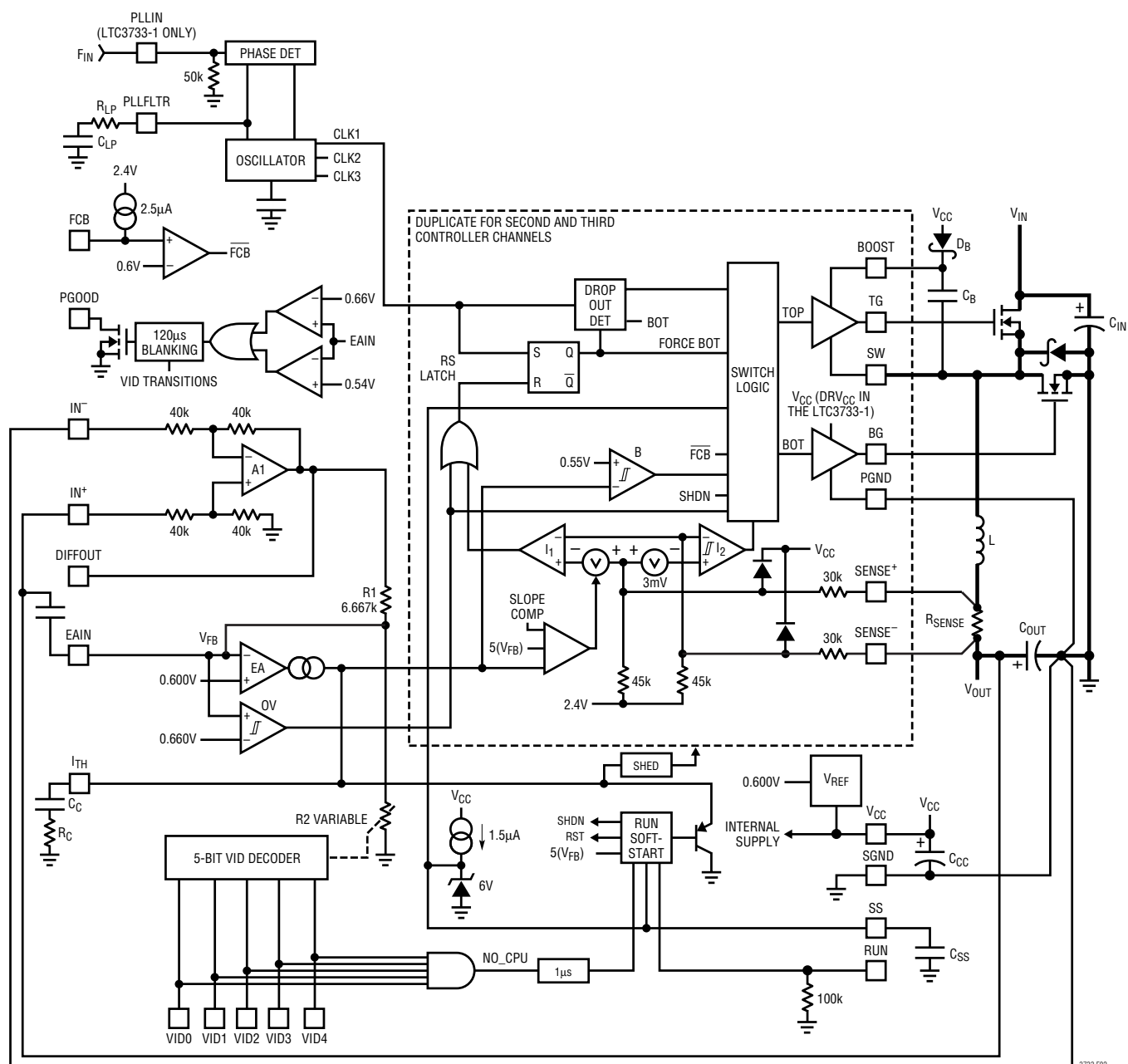


Figure 2

## OPERATION (Refer to Functional Diagram)

### Main Control Loop

The IC uses a constant frequency, current mode step-down architecture. During normal operation, each top MOSFET is turned on each cycle when the oscillator sets the RS latch, and turned off when the main current comparator,  $I_1$ , resets each RS latch. The peak inductor current at which  $I_1$  resets the RS latch is controlled by the voltage on the  $I_{TH}$  pin, which is the output of the error amplifier EA. The EAIN pin receives a portion of the voltage feedback signal via the DIFFOUT pin through the internal VID DAC and is compared to the internal reference voltage. When the load current increases, it causes a slight decrease in the EAIN pin voltage relative to the 0.6V reference, which in turn causes the  $I_{TH}$  voltage to increase until each inductor's average current matches one third of the new load current (assuming all three current sensing resistors are equal). In Burst Mode operation and stage shedding mode, after each top MOSFET has turned off, the bottom MOSFET is turned on until either the inductor current starts to reverse, as indicated by current comparator  $I_2$ , or the beginning of the next cycle.

The top MOSFET drivers are biased from floating bootstrap capacitor  $C_B$ , which is normally recharged during each off cycle through an external Schottky diode. When  $V_{IN}$  decreases to a voltage close to  $V_{OUT}$ , however, the loop may enter dropout and attempt to turn on the top MOSFET continuously. The dropout detector counts the number of oscillator cycles that the bottom MOSFET remains off and periodically forces a brief on period to allow  $C_B$  to recharge.

The main control loop is shut down by pulling the RUN pin low. Releasing RUN allows an internal 1.5 $\mu$ A current source to charge soft-start capacitor  $C_{SS}$  at the SS pin. The internal  $I_{TH}$  voltage is then clamped to the SS voltage when  $C_{SS}$  is slowly charged up. This "soft-start" clamping prevents abrupt current from being drawn from the input power source. When the RUN pin is low, all functions are kept in a controlled state.

### Low Current Operation

The FCB pin is a multifunction pin: 1) an analog comparator input to provide regulation for a secondary winding by

forcing temporary forced PWM operation and 2) a logic input to select between three modes of operation.

When the FCB pin voltage is below 0.6V, the controller performs as a continuous, PWM current mode synchronous switching regulator. The top and bottom MOSFETs are alternately turned on to maintain the output voltage independent of direction of inductor current. When the FCB pin is below  $V_{CC} - 1V$  but greater than 0.6V, the controller performs as a Burst Mode switching regulator. Burst Mode operation sets a minimum output current level before turning off the top switch and turns off the synchronous MOSFET(s) when the inductor current goes negative. This combination of requirements will, at low current, force the  $I_{TH}$  pin below a voltage threshold that will temporarily shut off both output MOSFETs until the output voltage drops slightly. There is a burst comparator having 60mV of hysteresis tied to the  $I_{TH}$  pin. This hysteresis results in output signals to the MOSFETs that turn them on for several cycles, followed by a variable "sleep" interval depending upon the load current. The resultant output voltage ripple is held to a very small value by having the hysteretic comparator after the error amplifier gain block.

When the FCB pin is tied to the  $V_{CC}$  pin, Burst Mode operation is disabled and the forced minimum inductor current requirement is removed. This provides constant frequency, discontinuous current operation over the widest possible output current range. At approximately 10% of maximum designed load current, the second and third output stages are shut off and the first controller alone is active in discontinuous current mode. This "stage shedding" optimizes efficiency by eliminating the gate charging losses and switching losses of the other two output stages. Additional cycles will be skipped when the output load current drops below 1% of maximum designed load current in order to maintain the output voltage. This constant frequency operation is not as efficient as Burst Mode operation at very light loads, but does provide lower noise, constant frequency operating mode down to very light load conditions.

Tying the FCB pin to ground will force continuous current operation. This is the least efficient operating mode, but may be desirable in certain applications. The output can

## OPERATION (Refer to Functional Diagram)

source or sink current in this mode. When forcing continuous operation and sinking current, this current will be forced back into the main power supply, potentially boosting the input supply to dangerous voltage levels—**BEWARE!**

### Frequency Synchronization or Setup

The phase-locked loop allows the internal oscillator to be synchronized to an external source using the PLLIN pin. The output of the phase detector at the PLLFLTR pin is also the DC frequency control input of the oscillator which operates over a 210kHz to 530kHz range corresponding to a voltage input from 0V to 2.4V. When locked, the PLL aligns the turn on of the top MOSFET to the rising edge of the synchronizing signal. When no frequency information is supplied to the PLLIN pin, PLLFLTR goes low, forcing the oscillator to minimum frequency. A DC source can be applied to the PLLFLTR pin to externally set the desired operating frequency.

In the G36 package, the PLLIN pin is not brought out and the PLLFLTR pin is for frequency setup only.

### Differential Amplifier

This amplifier provides true differential output voltage sensing. Sensing both  $V_{OUT}^+$  and  $V_{OUT}^-$  benefits regulation in high current applications and/or applications having electrical interconnection losses. This sensing also isolates the physical power ground from the physical signal ground preventing the possibility of troublesome “ground loops” on the PC layout and prevents voltage errors caused by board-to-board interconnects, particularly helpful in VRM designs.

### Power Good

The PGOOD pin is connected to the drain of an internal MOSFET. The MOSFET is turned on once the output voltage has been away from its nominal value by greater than 10%. The PGOOD signal is blanked for approximately 120 $\mu$ s during VID transitions. If a new VID transition occurs before the previous blanking time expires, the timer is reset.

### Short-Circuit Detection

The SS capacitor is used initially to limit the inrush current from the input power source. Once the controllers have been given time, as determined by the capacitor on the SS pin, to charge up the output capacitors and provide full load current, the SS capacitor is then used as a short-circuit timeout circuit. If the output voltage falls to less than 70% of its nominal output voltage, the SS capacitor begins discharging, assuming that the output is in a severe overcurrent and/or short-circuit condition. If the condition lasts for a long enough period, as determined by the size of the SS capacitor, the controller will be shut down until the RUN pin voltage is recycled. This built-in latchoff can be overridden by providing  $>5\mu$ A at a compliance of 4V to the SS pin. This current shortens the soft-start period but prevents net discharge of the SS capacitor during a severe overcurrent and/or short-circuit condition. Foldback current limiting is activated when the output voltage falls below 70% of its nominal level whether or not the short-circuit latchoff circuit is enabled. Foldback current limit can be overridden by clamping the EAIN pin such that the voltage is held above the (70%)(0.6V) or 0.42V level even when the actual output voltage is low.

The SS capacitor will be reset if the input voltage, ( $V_{CC}$ ) is allowed to fall below approximately 4V. The capacitor on the pin will be discharged until the short-circuit arming latch is disarmed. The SS capacitor will attempt to cycle through a normal soft-start ramp up after the  $V_{CC}$  supply rises above 4V. This circuit prevents power supply latchoff in the event of input power switching break-before-make situations.

### No\_CPU Detection

The LTC3733 detects the presense of CPU by monitoring all VID bits. If an all-“1” condition is detected, the controller acknowledges a No\_CPU fault. If this fault condition persists for more than 1 $\mu$ s, the SS pin is pulled low and the controller is shut down.

## APPLICATIONS INFORMATION

The basic application circuit is shown in Figure 1 on the first page of this data sheet. External component selection is driven by the load requirement, and normally begins with the selection of an inductance value based upon the desired operating frequency, inductor current and output voltage ripple requirements. Once the inductors and operating frequency have been chosen, the current sensing resistors can be calculated. Next, the power MOSFETs and Schottky diodes are selected. Finally,  $C_{IN}$  and  $C_{OUT}$  are selected according to the required voltage ripple requirements. The circuit shown in Figure 1 can be configured for operation up to a MOSFET supply voltage of 28V (limited by the external MOSFETs).

### Operating Frequency

The IC uses a constant frequency architecture with the frequency determined by an internal capacitor. This capacitor is charged by a fixed current plus an additional current which is proportional to the voltage applied to the PLLFLTR pin. Refer to the Phase-Locked Loop and Frequency Synchronization and Setup sections for additional information.

A graph for the voltage applied to the PLLFLTR pin versus frequency is given in Figure 3. As the operating frequency is increased the gate charge losses will be higher, reducing efficiency (see Efficiency Considerations). The maximum switching frequency is approximately 530kHz.

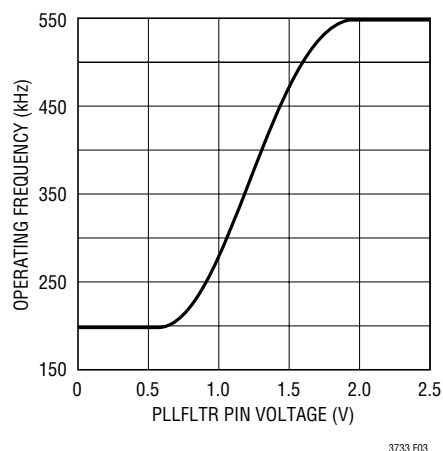


Figure 3. Operating Frequency vs  $V_{PLLFLTR}$

### Inductor Value Calculation and Output Ripple Current

The operating frequency and inductor selection are inter-related in that higher operating frequencies allow the use of smaller inductor and capacitor values. So why would anyone ever choose to operate at lower frequencies with larger components? The answer is efficiency. A higher frequency generally results in lower efficiency because of MOSFET gate charge and transition losses. In addition to this basic tradeoff, the effect of inductor value on ripple current and low current operation must also be considered. The PolyPhase approach reduces both input and output ripple currents while optimizing individual output stages to run at a lower fundamental frequency, enhancing efficiency.

The inductor value has a direct effect on ripple current. The inductor ripple current  $\Delta I_L$  per individual section,  $N$ , decreases with higher inductance or frequency and increases with higher  $V_{IN}$  or  $V_{OUT}$ :

$$\Delta I_L = \frac{V_{OUT}}{fL} \left( 1 - \frac{V_{OUT}}{V_{IN}} \right)$$

where  $f$  is the individual output stage operating frequency.

In a PolyPhase converter, the net ripple current seen by the output capacitor is much smaller than the individual inductor ripple currents due to the ripple cancellation. The details on how to calculate the net output ripple current can be found in Application Note 77.

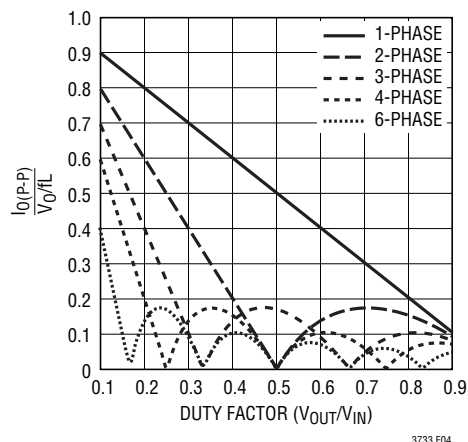
Figure 4 shows the net ripple current seen by the output capacitors for the different phase configurations. The output ripple current is plotted for a fixed output voltage as the duty factor is varied between 10% and 90% on the x-axis. The output ripple current is normalized against the inductor ripple current at zero duty factor. The graph can be used in place of tedious calculations. As shown in Figure 4, the zero output ripple current is obtained when:

$$\frac{V_{OUT}}{V_{IN}} = \frac{k}{N} \quad \text{where } k = 1, 2, \dots, N-1$$

## APPLICATIONS INFORMATION

So the number of phases used can be selected to minimize the output ripple current and therefore the output ripple voltage at the given input and output voltages. In applications having a highly varying input voltage, additional phases will produce the best results.

Accepting larger values of  $\Delta I_L$  allows the use of low inductances but can result in higher output voltage ripple. A reasonable starting point for setting ripple current is  $\Delta I_L = 0.4(I_{OUT})/N$ , where N is the number of channels and  $I_{OUT}$  is the total load current. Remember, the maximum  $\Delta I_L$  occurs at the maximum input voltage. The individual inductor ripple currents are constant determined by the inductor, input and output voltages.



**Figure 4. Normalized Peak Output Current vs Duty Factor [ $I_{RMS} = 0.3(I_{O(P-P)})$ ]**

### Inductor Core Selection

Once the value for L1 to L3 is known, the type of inductor must be selected. High efficiency converters generally cannot afford the core loss found in low cost powdered iron cores, forcing the use of ferrite, molypermalloy or Kool M $\mu$ ® cores. Actual core loss is independent of core size for a fixed inductor value, but it is very dependent on inductance selected. As inductance increases, core losses go down. Unfortunately, increased inductance requires more turns of wire and therefore copper losses will increase.

Ferrite designs have very low core loss and are preferred at high switching frequencies, so design goals can concentrate on copper loss and preventing saturation. Ferrite core material saturates “hard,” which means that inductance collapses abruptly when the peak design current is exceeded. This results in an abrupt increase in inductor ripple current and consequent output voltage ripple. Do not allow the core to saturate!

### Power MOSFET and D1, D2, D3 Selection

At least two external power MOSFETs must be selected for each of the three output sections: One N-channel MOSFET for the top (main) switch and one or more N-channel MOSFET(s) for the bottom (synchronous) switch. The number, type and “on” resistance of all MOSFETs selected take into account the voltage step-down ratio as well as the actual position (main or synchronous) in which the MOSFET will be used. A much smaller and much lower input capacitance MOSFET should be used for the top MOSFET in applications that have an output voltage that is less than 1/3 of the input voltage. In applications where  $V_{IN} \gg V_{OUT}$ , the top MOSFETs’ “on” resistance is normally less important for overall efficiency than its input capacitance at operating frequencies above 300kHz. MOSFET manufacturers have designed special purpose devices that provide reasonably low “on” resistance with significantly reduced input capacitance for the main switch application in switching regulators.

The peak-to-peak MOSFET gate drive levels are set by the voltage,  $V_{CC}$ , requiring the use of logic-level threshold MOSFETs in most applications. Pay close attention to the  $BV_{DSS}$  specification for the MOSFETs as well; many of the logic-level MOSFETs are limited to 30V or less.

Selection criteria for the power MOSFETs include the “on” resistance  $R_{SD(ON)}$ , input capacitance, input voltage and maximum output current.

MOSFET input capacitance is a combination of several components but can be taken from the typical “gate charge” curve included on most data sheets (Figure 5). The curve is generated by forcing a constant input current

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## APPLICATIONS INFORMATION

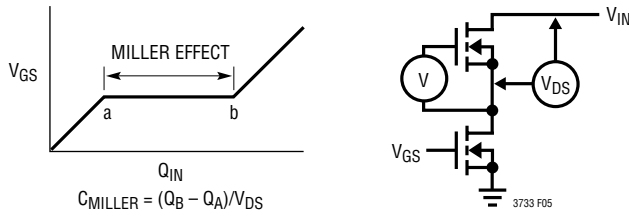


Figure 5. Gate Charge Characteristic

into the gate of a common source, current source loaded stage and then plotting the gate voltage versus time. The initial slope is the effect of the gate-to-source and the gate-to-drain capacitance. The flat portion of the curve is the result of the Miller capacitance effect of the drain-to-source capacitance as the drain drops the voltage across the current source load. The upper sloping line is due to the drain-to-gate accumulation capacitance and the gate-to-source capacitance. The Miller charge (the increase in coulombs on the horizontal axis from a to b while the curve is flat) is specified for a given  $V_{DS}$  drain voltage, but can be adjusted for different  $V_{DS}$  voltages by multiplying by the ratio of the application  $V_{DS}$  to the curve specified  $V_{DS}$  values. A way to estimate the  $C_{MILLER}$  term is to take the change in gate charge from points a and b on a manufacturers data sheet and divide by the stated  $V_{DS}$  voltage specified.  $C_{MILLER}$  is the most important selection criteria for determining the transition loss term in the top MOSFET but is not directly specified on MOSFET data sheets.  $C_{RSS}$  and  $C_{OS}$  are specified sometimes but definitions of these parameters are not included.

When the controller is operating in continuous mode the duty cycles for the top and bottom MOSFETs are given by:

$$\text{Main Switch Duty Cycle} = \frac{V_{OUT}}{V_{IN}}$$

$$\text{Synchronous Switch Duty Cycle} = \left( \frac{V_{IN} - V_{OUT}}{V_{IN}} \right)$$

The power dissipation for the main and synchronous MOSFETs at maximum output current are given by:

$$P_{MAIN} = \frac{V_{OUT}}{V_{IN}} \left( \frac{I_{MAX}}{N} \right)^2 (1 + \delta) R_{DS(ON)} +$$

$$V_{IN}^2 \frac{I_{MAX}}{2N} (R_{DR}) (C_{MILLER}) \cdot$$

$$\left[ \frac{1}{V_{CC} - V_{TH(MIN)}} + \frac{1}{V_{TH(MIN)}} \right] (f)$$

$$P_{SYNC} = \frac{V_{IN} - V_{OUT}}{V_{IN}} \left( \frac{I_{MAX}}{N} \right)^2 (1 + \delta) R_{DS(ON)}$$

where  $N$  is the number of output stages,  $\delta$  is the temperature dependency of  $R_{DS(ON)}$ ,  $R_{DR}$  is the effective top driver resistance (approximately  $2\Omega$  at  $V_{GS} = V_{MILLER}$ ),  $V_{IN}$  is the drain potential *and* the change in drain potential in the particular application.  $V_{TH(MIN)}$  is the data sheet specified typical gate threshold voltage specified in the power MOSFET data sheet.  $C_{MILLER}$  is the calculated capacitance using the gate charge curve from the MOSFET data sheet and the technique described above.

Both MOSFETs have  $I^2R$  losses while the topside N-channel equation includes an additional term for transition losses, which peak at the highest input voltage. For  $V_{IN} < 12V$ , the high current efficiency generally improves with larger MOSFETs, while for  $V_{IN} > 12V$ , the transition losses rapidly increase to the point that the use of a higher  $R_{DS(ON)}$  device with lower  $C_{RSS}$  actually provides higher efficiency. The synchronous MOSFET losses are greatest at high input voltage when the top switch duty factor is low or during a short circuit when the synchronous switch is on close to 100% of the period.

The term  $(1 + \delta)$  is generally given for a MOSFET in the form of a normalized  $R_{DS(ON)}$  vs temperature curve, but

## APPLICATIONS INFORMATION

$\delta = 0.005/^{\circ}\text{C}$  can be used as an approximation for low voltage MOSFETs.

The Schottky diodes, D1 to D3 shown in Figure 1 conduct during the dead time between the conduction of the two large power MOSFETs. This prevents the body diode of the bottom MOSFET from turning on, storing charge during the dead time and requiring a reverse recovery period which could cost as much as several percent in efficiency. A 2A to 8A Schottky is generally a good compromise for both regions of operation due to the relatively small average current. Larger diodes result in additional transition losses due to their larger junction capacitance.

### $C_{IN}$ and $C_{OUT}$ Selection

Input capacitance ESR requirements and efficiency losses are reduced substantially in a multiphase architecture because the peak current drawn from the input capacitor is effectively divided by the number of phases used and power loss is proportional to the RMS current squared. A 3-stage, single output voltage implementation can reduce input path power loss by 90%.

In continuous mode, the source current of each top N-channel MOSFET is a square wave of duty cycle  $V_{OUT}/V_{IN}$ . A low ESR input capacitor sized for the maximum RMS current must be used. The details of a close form equation can be found in Application Note 77. Figure 6 shows the input capacitor ripple current for different phase configurations with the output voltage fixed and input voltage varied. The input ripple current is normalized against the DC output current. The graph can be used in place of tedious calculations. The minimum input ripple current can be achieved when the product of phase number and output voltage,  $N(V_{OUT})$ , is approximately equal to the input voltage  $V_{IN}$  or:

$$\frac{V_{OUT}}{V_{IN}} = \frac{k}{N} \text{ where } k = 1, 2, \dots, N-1$$

So the phase number can be chosen to minimize the input capacitor size for the given input and output voltages.

In the graph of Figure 6, the local maximum input RMS capacitor currents are reached when:

$$\frac{V_{OUT}}{V_{IN}} = \frac{2k-1}{N} \text{ where } k = 1, 2, \dots, N$$

These worst-case conditions are commonly used for design because even significant deviations do not offer much relief. Note that capacitor manufacturer's ripple current ratings are often based on only 2000 hours of life. This makes it advisable to further derate the capacitor or to choose a capacitor rated at a higher temperature than required. Several capacitors may also be paralleled to meet size or height requirements in the design. Always consult the capacitor manufacturer if there is any question.

The Figure 6 graph shows that the peak RMS input current is reduced linearly, inversely proportional to the number  $N$  of stages used. It is important to note that the efficiency loss is proportional to the input RMS current squared and therefore a 3-stage implementation results in 90% less power loss when compared to a single phase design. Battery/input protection fuse resistance (if used), PC

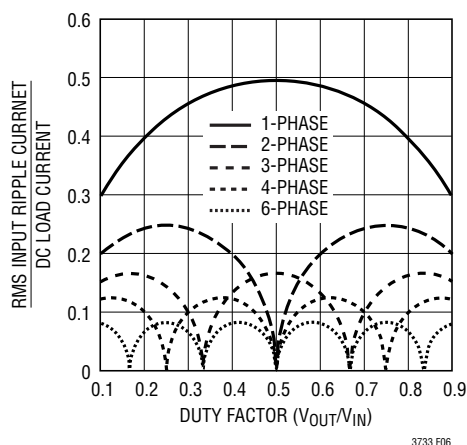


Figure 6. Normalized Input RMS Ripple Current vs Duty Factor for One to Six Output Stages

## APPLICATIONS INFORMATION

board trace and connector resistance losses are also reduced by the reduction of the input ripple current in a PolyPhase system. The required amount of input capacitance is further reduced by the factor, N, due to the effective increase in the frequency of the current pulses.

Ceramic capacitors are becoming very popular for small designs but several cautions should be observed. “X7R”, “X5R” and “Y5V” are examples of a few of the ceramic materials used as the dielectric layer, and these different dielectrics have very different effect on the capacitance value due to the voltage and temperature conditions applied. Physically, if the capacitance value changes due to applied voltage change, there is a concomitant piezo effect which results in radiating sound! A load that draws varying current at an audible rate may cause an attendant varying input voltage on a ceramic capacitor, resulting in an audible signal. A secondary issue relates to the energy flowing back into a ceramic capacitor whose capacitance value is being reduced by the increasing charge. The voltage can increase at a considerably higher rate than the constant current being supplied because the capacitance value is decreasing as the voltage is increasing! Ceramic capacitors, when properly selected and used however, can provide the lowest overall loss due to their extremely low ESR.

The selection of  $C_{OUT}$  is driven by the required effective series resistance (ESR). Typically once the ESR requirement is satisfied the capacitance is adequate for filtering. The steady-state output ripple ( $\Delta V_{OUT}$ ) is determined by:

$$\Delta V_{OUT} \approx \Delta I_{RIPPLE} \left( ESR + \frac{1}{8NfC_{OUT}} \right)$$

where  $f$  = operating frequency of each stage, N is the number of output stages,  $C_{OUT}$  = output capacitance and  $\Delta I_L$  = ripple current in each inductor. The output ripple is highest at maximum input voltage since  $\Delta I_L$  increases

with input voltage. The output ripple will be less than 50mV at max  $V_{IN}$  with  $\Delta I_L = 0.4I_{OUT(MAX)}$  assuming:

$$C_{OUT} \text{ required ESR} < N \cdot R_{SENSE}$$

and

$$C_{OUT} > 1/(8Nf)(R_{SENSE})$$

The emergence of very low ESR capacitors in small, surface mount packages makes very small physical implementations possible. The ability to externally compensate the switching regulator loop using the  $I_{TH}$  pin allows a much wider selection of output capacitor types. The impedance characteristics of each capacitor type is significantly different than an ideal capacitor and therefore requires accurate modeling or bench evaluation during design.

Manufacturers such as Nichicon, United Chemicon and Sanyo should be considered for high performance through-hole capacitors. The OS-CON semiconductor dielectric capacitor available from Sanyo and the Panasonic SP surface mount types have a good (ESR)(size) product. Once the ESR requirement for  $C_{OUT}$  has been met, the RMS current rating generally far exceeds the  $I_{RIPPLE(P-P)}$  requirement. Ceramic capacitors from AVX, Taiyo Yuden, Murata and Tokin offer high capacitance value and very low ESR, especially applicable for low output voltage applications.

In surface mount applications, multiple capacitors may have to be paralleled to meet the ESR or RMS current handling requirements of the application. Aluminum electrolytic and dry tantalum capacitors are both available in surface mount configurations. New special polymer surface mount capacitors offer very low ESR also but have much lower capacitive density per unit volume. In the case of tantalum, it is critical that the capacitors are surge tested for use in switching power supplies. Several excellent choices are the AVX TPS, AVX TPSV, the KEMET T510

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series of surface-mount tantalums or the Panasonic SP series of surface mount special polymer capacitors available in case heights ranging from 2mm to 4mm. Other capacitor types include Sanyo POS-CAP, Sanyo OS-CON, Nichicon PL series and Sprague 595D series. Consult the manufacturer for other specific recommendations.

### R<sub>SENSE</sub> Selection for Output Current

Once the frequency and inductor have been chosen, R<sub>SENSE1</sub>, R<sub>SENSE2</sub>, R<sub>SENSE3</sub> are determined based on the required peak inductor current. The current comparator has a maximum threshold of 75mV/R<sub>SENSE</sub> and an input common mode range of SGND to (1.1) • V<sub>CC</sub>. The current comparator threshold sets the peak inductor current, yielding a maximum average output current I<sub>MAX</sub> equal to the peak value less half the peak-to-peak ripple current,  $\Delta I_L$ .

Allowing a margin for variations in the IC and external component values yields:

$$R_{SENSE} = N \frac{50\text{mV}}{I_{MAX}}$$

The IC works well with values of R<sub>SENSE</sub> from 0.001Ω to 0.02Ω.

### V<sub>CC</sub> Decoupling

The V<sub>CC</sub> pin supplies power not only the internal circuits of the controller but also the top and bottom gate drivers and therefore must be bypassed very carefully to ground with a ceramic capacitor, type X7R or X5R (depending upon the operating temperature environment) of *at least 1μF immediately next to the IC* and preferably an additional 10μF placed very close to the IC due to the extremely high instantaneous currents involved. The total capacitance, taking into account the voltage coefficient of ceramic capacitors, should be 100 times as large as the total combined gate charge capacitance of ALL of the MOSFETs being driven. Good bypassing close to the IC is necessary

to supply the high transient currents required by the MOSFET gate drivers while keeping the 5V supply quiet enough so as not to disturb the very small-signal high bandwidth of the current comparators.

### Topside MOSFET Driver Supply (C<sub>B</sub>, D<sub>B</sub>)

External bootstrap capacitors, C<sub>B</sub>, connected to the BOOST pins, supply the gate drive voltages for the topside MOSFETs. Capacitor C<sub>B</sub> in the Functional Diagram is charged through diode D<sub>B</sub> from V<sub>CC</sub> when the SW pin is low. When one of the topside MOSFETs turns on, the driver places the C<sub>B</sub> voltage across the gate-source of the desired MOSFET. This enhances the MOSFET and turns on the topside switch. The switch node voltage, SW, rises to V<sub>IN</sub> and the BOOST pin follows. With the topside MOSFET on, the boost voltage is above the input supply (V<sub>BOOST</sub> = V<sub>CC</sub> + V<sub>IN</sub>). The value of the boost capacitor C<sub>B</sub> needs to be 30 to 100 times that of the total input capacitance of the topside MOSFET(s). The reverse breakdown of D<sub>B</sub> must be greater than V<sub>IN(MAX)</sub>.

### Differential Amplifier

The IC has a true remote voltage sense capability. The sensing connections should be returned from the load, back to the differential amplifier's inputs through a common, tightly coupled pair of PC traces. The differential amplifier rejects common mode signals capacitively or inductively radiated into the feedback PC traces as well as ground loop disturbances. The differential amplifier output signal is divided down through the VID DAC and is compared with the internal, precision 0.6V voltage reference by the error amplifier.

The amplifier has a 0 to V<sub>CC</sub> common mode input range and an output swing range of 0 to V<sub>CC</sub> – 1.2V. The output uses an NPN emitter follower with 80kΩ feedback resistance. A DC resistive load to ground is required in order to sink more current.

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### Output Voltage

The IC includes a digitally controlled 5-bit attenuator producing output voltages as defined in Table 1. Output voltages with 25mV increments are produced from 0.8V to 1.55V.

Each VID digital input is pulled up to a logical high with an internal 150k resistor. The input logic threshold is approximately 1.2V but the input circuit can withstand an input voltage of up to 7V.

### ON/OFF Control

The RUN pin provides simple ON/OFF control for the LTC3733. Driving the RUN pin above 1.5V permits the controller to start operating. Pulling RUN below 0.8V puts the LTC3733 into low current shutdown ( $I_Q \approx 20\mu\text{A}$ ).

### Soft-Start Function

The SS pin provides two functions: 1) soft-start and 2) a defeatable short-circuit latch off timer. Soft-start reduces the input power sources' surge currents by gradually increasing the controller's current limit (proportional to an internal buffered and clamped  $V_{\text{ITH}}$ ). The latchoff timer prevents very short, extreme load transients from tripping the overcurrent latch. A small pull-up current ( $>5\mu\text{A}$ ) supplied to the SS pin will prevent the overcurrent latch from operating. The following explanation describes how this function operates.

An internal  $1.5\mu\text{A}$  current source charges up the  $C_{\text{SS}}$  capacitor. As the voltage on SS increases from 0V to 2.4V, the internal current limit is increased from  $0\text{V}/R_{\text{SENSE}}$  to  $75\text{mV}/R_{\text{SENSE}}$ . The output current limit ramps up slowly, taking  $1.6\text{s}/\mu\text{F}$  to reach full current. The output current thus ramps up slowly, eliminating the starting surge current required from the input power supply.

$$t_{\text{IRAMP}} = \frac{2.4\text{V} - 0\text{V}}{1.5\mu\text{A}} C_{\text{SS}} = (1.6\text{s}/\mu\text{F}) C_{\text{SS}}$$

The SS pin has an internal 6V zener clamp (see the Functional Diagram).

Table 1. VID Output Voltage Programming

| VID4 | VID3 | VID2 | VID1 | VID0 | V <sub>OUT</sub> |
|------|------|------|------|------|------------------|
| 0    | 0    | 0    | 0    | 0    | 1.550            |
| 0    | 0    | 0    | 0    | 1    | 1.525            |
| 0    | 0    | 0    | 1    | 0    | 1.500            |
| 0    | 0    | 0    | 1    | 1    | 1.475            |
| 0    | 0    | 1    | 0    | 0    | 1.450            |
| 0    | 0    | 1    | 0    | 1    | 1.425            |
| 0    | 0    | 1    | 1    | 0    | 1.400            |
| 0    | 0    | 1    | 1    | 1    | 1.375            |
| 0    | 1    | 0    | 0    | 0    | 1.350            |
| 0    | 1    | 0    | 0    | 1    | 1.325            |
| 0    | 1    | 0    | 1    | 0    | 1.300            |
| 0    | 1    | 0    | 1    | 1    | 1.275            |
| 0    | 1    | 1    | 0    | 0    | 1.250            |
| 0    | 1    | 1    | 0    | 1    | 1.225            |
| 0    | 1    | 1    | 1    | 0    | 1.200            |
| 0    | 1    | 1    | 1    | 1    | 1.175            |
| 1    | 0    | 0    | 0    | 0    | 1.150            |
| 1    | 0    | 0    | 0    | 1    | 1.125            |
| 1    | 0    | 0    | 1    | 0    | 1.100            |
| 1    | 0    | 0    | 1    | 1    | 1.075            |
| 1    | 0    | 1    | 0    | 0    | 1.050            |
| 1    | 0    | 1    | 0    | 1    | 1.025            |
| 1    | 0    | 1    | 1    | 0    | 1.000            |
| 1    | 0    | 1    | 1    | 1    | 0.975            |
| 1    | 1    | 0    | 0    | 0    | 0.950            |
| 1    | 1    | 0    | 0    | 1    | 0.925            |
| 1    | 1    | 0    | 1    | 0    | 0.900            |
| 1    | 1    | 0    | 1    | 1    | 0.875            |
| 1    | 1    | 1    | 0    | 0    | 0.850            |
| 1    | 1    | 1    | 0    | 1    | 0.825            |
| 1    | 1    | 1    | 1    | 0    | 0.800            |
| 1    | 1    | 1    | 1    | 1    | Shutdown         |

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### Fault Conditions: Overcurrent Latchoff

The SS pin also provides the ability to latch off the controllers when an overcurrent condition is detected. The SS capacitor is used initially to limit the inrush current of all three output stages. After the controllers have been given adequate time to charge up the output capacitor and provide full load current, the SS capacitor is used for a short-circuit timer. If the output voltage falls to less than 70% of its nominal value, the SS capacitor begins discharging on the assumption that the output is in an overcurrent condition. If the condition lasts for a long enough period, as determined by the size of the SS capacitor, the controller will be shut down until the RUN pin voltage is recycled. If the overload occurs during start-up, the time can be approximated by:

$$t_{LO1} \gg (C_{SS} \cdot 0.6V) / (1.5\mu A) = 4 \cdot 10^5 (C_{SS})$$

If the overload occurs after start-up, the voltage on the SS capacitor will continue charging and will provide additional time before latching off:

$$t_{LO2} \gg (C_{SS} \cdot 3V) / (1.5\mu A) = 2 \cdot 10^6 (C_{SS})$$

This built-in overcurrent latchoff can be overridden by providing a pull-up resistor to the SS pin from  $V_{CC}$  as shown in Figure 7. When  $V_{CC}$  is 5V, a 200k resistance will prevent the discharge of the SS capacitor during an overcurrent condition but also shortens the soft-start period, so a larger SS capacitor value will be required.

Why should you defeat overcurrent latchoff? During the prototyping stage of a design, there may be a problem with noise pick-up or poor layout causing the protection circuit

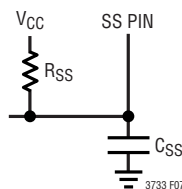


Figure 7. Defeating Overcurrent Latchoff

to latch off the controller. Defeating this feature allows troubleshooting of the circuit and PC layout. The internal foldback current limiting still remains active, thereby protecting the power supply system from failure. A decision can be made after the design is complete whether to rely solely on foldback current limiting or to enable the latchoff feature by removing the pull-up resistor.

The value of the soft-start capacitor  $C_{SS}$  may need to be scaled with output current, output capacitance and load current characteristics. The minimum soft-start capacitance is given by:

$$C_{SS} > (C_{OUT})(V_{OUT})(10^{-4})(R_{SENSE})$$

The minimum recommended soft-start capacitor of  $C_{SS} = 0.1\mu F$  will be sufficient for most applications.

### Current Foldback

In certain applications, it may be desirable to defeat the internal current foldback function. A negative impedance is experienced when powering a switching regulator. That is, the input current is higher at a lower  $V_{IN}$  and decreases as  $V_{IN}$  is increased. Current foldback is designed to accommodate a normal, resistive load having increasing current draw with increasing voltage. The EAIN pin should be artificially held 70% above its nominal operating level of 0.6V, or 0.42V in order to prevent the IC from “folding back” the peak current level. A suggested circuit is shown in Figure 8.

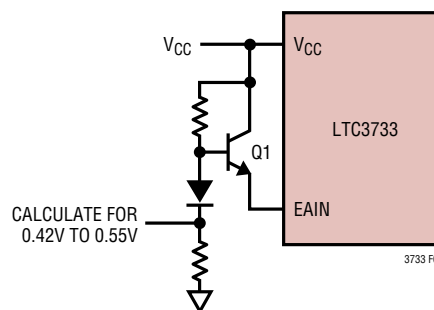


Figure 8. Foldback Current Elimination

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The emitter of Q1 will hold up the EAIN pin to a voltage in the absence of  $V_{OUT}$  that will prevent the internal sensing circuitry from reducing the peak output current. Removing the function in this manner eliminates the external MOSFET's protective feature under short-circuit conditions. This technique will also prevent the short-circuit latchoff function from turning off the part during a short-circuit event and the output current will only be limited to  $N \cdot 75\text{mV}/R_{SENSE}$ .

### Undervoltage Reset

In the event that the input power source to the IC ( $V_{CC}$ ) drops below 4V, the SS capacitor will be discharged to ground and the controller will be shut down. When  $V_{CC}$  rises above 4V, the SS capacitor will be allowed to recharge and initiate another soft-start turn-on attempt. This may be useful in applications that switch between two supplies that are not diode connected, but note that this cannot make up for the resultant interruption of the regulated output.

### Phase-Locked Loop and Frequency Synchronization (LTC3733-1)

The IC has a phase-locked loop comprised of an internal voltage controlled oscillator and phase detector. This allows the top MOSFET of output stage 1's turn-on to be locked to the rising edge of an external source. The frequency range of the voltage controlled oscillator is  $\pm 50\%$  around the center frequency  $f_0$ . A voltage applied to the PLLFLTR pin of 1.2V corresponds to a frequency of approximately 350kHz. The nominal operating frequency range of the IC is 210kHz to 530kHz.

The phase detector used is an edge sensitive digital type that provides zero degrees phase shift between the external and internal oscillators. This type of phase detector will not lock the internal oscillator to harmonics of the input frequency. The PLL hold-in range,  $\Delta f_H$ , is equal to the capture range,  $\Delta f_C$ :

$$\Delta f_H = \Delta f_C = \pm 0.5 f_0$$

The output of the phase detector is a complementary pair of current sources charging or discharging the external filter components on the PLLFLTR pin. A simplified block diagram is shown in Figure 9.

If the external frequency ( $f_{PLLIN}$ ) is greater than the oscillator frequency,  $f_{OSC}$ , current is sourced continuously, pulling up the PLLFLTR pin. When the external frequency is less than  $f_{OSC}$ , current is sunk continuously, pulling down the PLLFLTR pin. If the external and internal frequencies are the same, but exhibit a phase difference, the current sources turn on for an amount of time corresponding to the phase difference. Thus, the voltage on the PLLFLTR pin is adjusted until the phase and frequency of the external and internal oscillators are identical. At this stable operating point, the phase comparator output is open and the filter capacitor  $C_{LP}$  holds the voltage. The IC PLLIN pin must be driven from a low impedance source such as a logic gate located close to the pin. When using multiple ICs for a phase-locked system, the PLLFLTR pin of the master oscillator should be biased at a voltage that will guarantee the slave oscillator(s) ability to lock onto the master's frequency. A voltage of 1.7V or below applied to the master oscillator's PLLFLTR pin is recommended in order to meet this requirement. The resultant operating frequency will be approximately 500kHz for 1.7V.

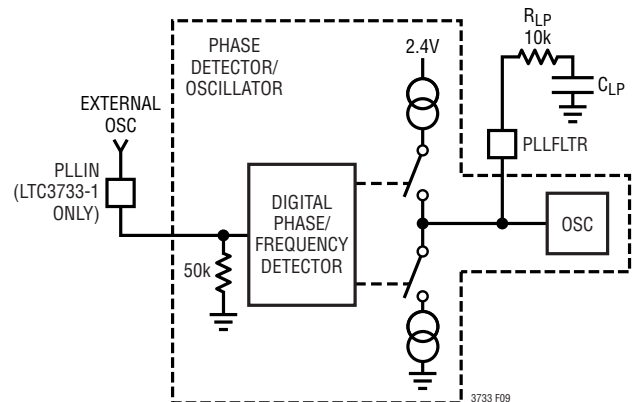


Figure 9. Phase-Locked Loop Block Diagram

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The loop filter components ( $C_{LP}$ ,  $R_{LP}$ ) smooth out the current pulses from the phase detector and provide a stable input to the voltage controlled oscillator. The filter components  $C_{LP}$  and  $R_{LP}$  determine how fast the loop acquires lock. Typically  $R_{LP} = 10k$  and  $C_{LP}$  ranges from  $0.01\mu F$  to  $0.1\mu F$ .

### Minimum On-Time Considerations

Minimum on-time,  $t_{ON(MIN)}$ , is the smallest time duration that the IC is capable of turning on the top MOSFET. It is determined by internal timing delays and the gate charge of the top MOSFET. Low duty cycle applications may approach this minimum on-time limit and care should be taken to ensure that:

$$t_{ON(MIN)} < \frac{V_{OUT}}{V_{IN}(f)}$$

If the duty cycle falls below what can be accommodated by the minimum on-time, the IC will begin to skip every other cycle, resulting in half-frequency operation. The output voltage will continue to be regulated, but the ripple current and ripple voltage will increase.

The minimum on-time for the IC is generally about 120ns. However, as the peak sense voltage decreases the minimum on-time gradually increases. This is of particular concern in forced continuous applications with low ripple current at light loads. If the duty cycle drops below the minimum on-time limit in this situation, a significant amount of cycle skipping can occur with correspondingly larger current and voltage ripple.

If an application can operate close to the minimum on-time limit, an inductor must be chosen that is low enough in value to provide sufficient ripple amplitude to meet the minimum on-time requirement. *As a general rule, keep the inductor ripple current equal to or greater than 30% of  $I_{OUT(MAX)}$  at  $V_{IN(MAX)}$ .*

### Efficiency Considerations

The percent efficiency of a switching regulator is equal to the output power divided by the input power times 100%.

It is often useful to analyze individual losses to determine what is limiting the efficiency and which change would produce the most improvement. Percent efficiency can be expressed as:

$$\% \text{Efficiency} = 100\% - (L1 + L2 + L3 + \dots)$$

where  $L1$ ,  $L2$ , etc. are the individual losses as a percentage of input power.

### Checking Transient Response

The regulator loop response can be checked by looking at the load transient response. Switching regulators take several cycles to respond to a step in DC (resistive) load current. When a load step occurs,  $V_{OUT}$  shifts by an amount equal to  $\Delta I_{LOAD} \cdot ESR$ , where ESR is the effective series resistance of  $C_{OUT}$ .  $\Delta I_{LOAD}$  also begins to charge or discharge  $C_{OUT}$ , generating the feedback error signal that forces the regulator to adapt to the current change and return  $V_{OUT}$  to its steady-state value. During this recovery time,  $V_{OUT}$  can be monitored for excessive overshoot or ringing, which would indicate a stability problem. **The availability of the  $I_{TH}$  pin not only allows optimization of control loop behavior, but also provides a DC coupled and AC filtered closed-loop response test point. The DC step, rise time and settling at this test point truly reflects the closed-loop response.** Assuming a predominantly second order system, phase margin and/or damping factor can be estimated using the percentage of overshoot seen at this pin. The bandwidth can also be estimated by examining the rise time at the pin. The  $I_{TH}$  external components shown in the Figure 1 circuit will provide an adequate starting point for most applications.

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The  $I_{TH}$  series  $R_C$ - $C_C$  filter sets the dominant pole-zero loop compensation. The values can be modified slightly (from 0.2 to 5 times their suggested values) to maximize transient response once the final PC layout is done and the particular output capacitor type and value have been determined. The output capacitors need to be decided upon because the various types and values determine the loop feedback factor gain and phase. An output current pulse of 20% to 80% of full load current having a rise time of  $< 2\mu s$  will produce output voltage and  $I_{TH}$  pin waveforms that will give a sense of the overall loop stability without breaking the feedback loop. The initial output voltage step, resulting from the step change in output current, may not be within the bandwidth of the feedback loop, so this signal cannot be used to determine phase margin. This is why it is better to look at the  $I_{TH}$  pin signal which is in the feedback loop and is the filtered and compensated control loop response. The gain of the loop will be increased by increasing  $R_C$  and the bandwidth of the loop will be increased by decreasing  $C_C$ . If  $R_C$  is increased by the same factor that  $C_C$  is decreased, the zero frequency will be kept the same, thereby keeping the phase the same in the most critical frequency range of the feedback loop. The output voltage settling behavior is related to the stability of the closed-loop system and will demonstrate the actual overall supply performance.

A second, more severe transient is caused by switching in loads with large ( $> 1\mu F$ ) supply bypass capacitors. The discharged bypass capacitors are effectively put in parallel with  $C_{OUT}$ , causing a rapid drop in  $V_{OUT}$ . No regulator can alter its delivery of current quickly enough to prevent this sudden step change in output voltage if the load switch resistance is low and it is driven quickly. If  $C_{LOAD}$  is greater than 2% of  $C_{OUT}$ , the switch rise time should be controlled so that the load rise time is limited to approximately  $1000 \cdot R_{SENSE} \cdot C_{LOAD}$ . Thus a  $250\mu F$  capacitor and a  $2m\Omega$

$R_{SENSE}$  resistor would require a  $500\mu s$  rise time, limiting the charging current to about 1A.

### Design Example (Using Three Phases)

As a design example, assume  $V_{IN} = 12V$  (nominal),  $V_{IN} = 20V$  (max),  $V_{OUT} = 1.3V$ ,  $I_{MAX} = 45A$  and  $f = 400kHz$ . The inductance value is chosen first based upon a 30% ripple current assumption. The highest value of ripple current in each output stage occurs at the maximum input voltage.

$$L = \frac{V_{OUT}}{f(\Delta I)} \left( 1 - \frac{V_{OUT}}{V_{IN}} \right)$$

$$= \frac{1.3V}{(400kHz)(30\%)(15A)} \left( 1 - \frac{1.3V}{20V} \right)$$

$$\geq 0.68\mu H$$

Using  $L = 0.6\mu H$ , a commonly available value results in 34% ripple current. The worst-case output ripple for the three stages operating in parallel will be less than 11% of the peak output current.

$R_{SENSE1}$ ,  $R_{SENSE2}$  and  $R_{SENSE3}$  can be calculated by using a conservative maximum sense current threshold of 65mV and taking into account half of the ripple current:

$$R_{SENSE} = \frac{65mV}{15A \left( 1 + \frac{34\%}{2} \right)} = 0.0037\Omega$$

Use a commonly available  $0.003\Omega$  sense resistor.

Next verify the minimum on-time is not violated. The minimum on-time occurs at maximum  $V_{CC}$ :

$$t_{ON(MIN)} = \frac{V_{OUT}}{V_{IN(MAX)}(f)} = \frac{1.3V}{20V(400kHz)} = 162ns$$

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The output voltage will be set by the VID code according to Table 1.

The power dissipation on the topside MOSFET can be estimated. Using a Fairchild FDS6688 for example,  $R_{DS(ON)} = 7\text{m}\Omega$ ,  $C_{MILLER} = 15\text{nC}/15\text{V} = 1000\text{pF}$ . At maximum input voltage with  $T(\text{estimated}) = 50^\circ\text{C}$ :

$$P_{\text{MAIN}} \approx \frac{1.8\text{V}}{20\text{V}} (15)^2 \left[ 1 + (0.005)(50^\circ\text{C} - 25^\circ\text{C}) \right] \\ 0.007\Omega + (20)^2 \left( \frac{45\text{A}}{(2)(3)} \right) (2\Omega)(1000\text{pF}) \\ \left( \frac{1}{5\text{V} - 1.8\text{V}} + \frac{1}{1.8\text{V}} \right) (400\text{kHz}) = 2.2\text{W}$$

The worst-case power dissipation by the synchronous MOSFET under normal operating conditions at elevated ambient temperature and estimated  $50^\circ\text{C}$  junction temperature rise is:

$$P_{\text{SYNC}} = \frac{20\text{V} - 1.3\text{V}}{20\text{V}} (15\text{A})^2 (1.25)(0.007\Omega) = 1.84\text{W}$$

A short circuit to ground will result in a folded back current of:

$$I_{\text{sc}} \approx \frac{25\text{mV}}{(2+3)\text{m}\Omega} + \frac{1}{2} \left( \frac{150\text{ns}(20\text{V})}{0.6\mu\text{H}} \right) = 7.5\text{A}$$

with a typical value of  $R_{DS(ON)}$  and  $d = (0.005/^\circ\text{C})(50^\circ\text{C}) = 0.25$ . The resulting power dissipated in the bottom MOSFET is:

$$P_{\text{SYNC}} = (7.5\text{A})^2 (1.25)(0.007\Omega) \approx 0.5\text{W}$$

which is less than one third of the normal, full load conditions. Incidentally, since the load no longer dissipates any power, total system power is decreased by over 90%. Therefore, the system actually cools significantly during a shorted condition!

### PC Board Layout Checklist

When laying out the printed circuit board, the following checklist should be used to ensure proper operation of the

IC. These items are also illustrated graphically in the layout diagram of Figure 10. Check the following in the PC layout:

1) Are the signal and power ground paths isolated? Keep the SGND at one end of a printed circuit path thus preventing MOSFET currents from traveling under the IC. The IC signal ground pin should be used to hook up all control circuitry on one side of the IC, routing the copper through SGND, under the IC covering the “shadow” of the package, connecting to the PGND pin and then continuing on to the (–) plates of  $C_{\text{IN}}$  and  $C_{\text{OUT}}$ . The  $V_{\text{CC}}$  decoupling capacitor should be placed immediately adjacent to the IC between the  $V_{\text{CC}}$  pin and PGND. A  $1\mu\text{F}$  ceramic capacitor of the X7R or X5R type is small enough to fit very close to the IC to minimize the ill effects of the large current pulses drawn to drive the bottom MOSFETs. An additional  $5\mu\text{F}$  to  $10\mu\text{F}$  of ceramic, tantalum or other very low ESR capacitance is recommended in order to keep the internal IC supply quiet. The power ground returns to the sources of the bottom N-channel MOSFETs, anodes of the Schottky diodes and (–) plates of  $C_{\text{IN}}$ , which should have as short lead lengths as possible.

2) Does the IC  $\text{IN}^+$  pin connect to the (+) plates of  $C_{\text{OUT}}$ ? A  $30\text{pF}$  to  $300\text{pF}$  feedforward capacitor between the DIFFOUT and EAIN pins should be placed as close as possible to the IC.

3) Are the SENSE<sup>–</sup> and SENSE<sup>+</sup> printed circuit traces for each channel routed together with minimum PC trace spacing? The filter capacitors between SENSE<sup>+</sup> and SENSE<sup>–</sup> for each channel should be as close as possible to the pins of the IC. Connect the SENSE<sup>–</sup> and SENSE<sup>+</sup> pins to the pads of the sense resistor as illustrated in Figure 11.

4) Do the (+) plates of  $C_{\text{IN}}$  connect to the drains of the topside MOSFETs as closely as possible? This capacitor provides the pulsed current to the MOSFETs.

5) Keep the switching nodes, SWITCH, BOOST and TG away from sensitive small-signal nodes. Ideally the SWITCH, BOOST and TG printed circuit traces should be routed away and separated from the IC and the “quiet” side of the IC.

6) The filter capacitors between the  $\text{I}_{\text{TH}}$  and SGND pins should be as close as possible to the pins of the IC.

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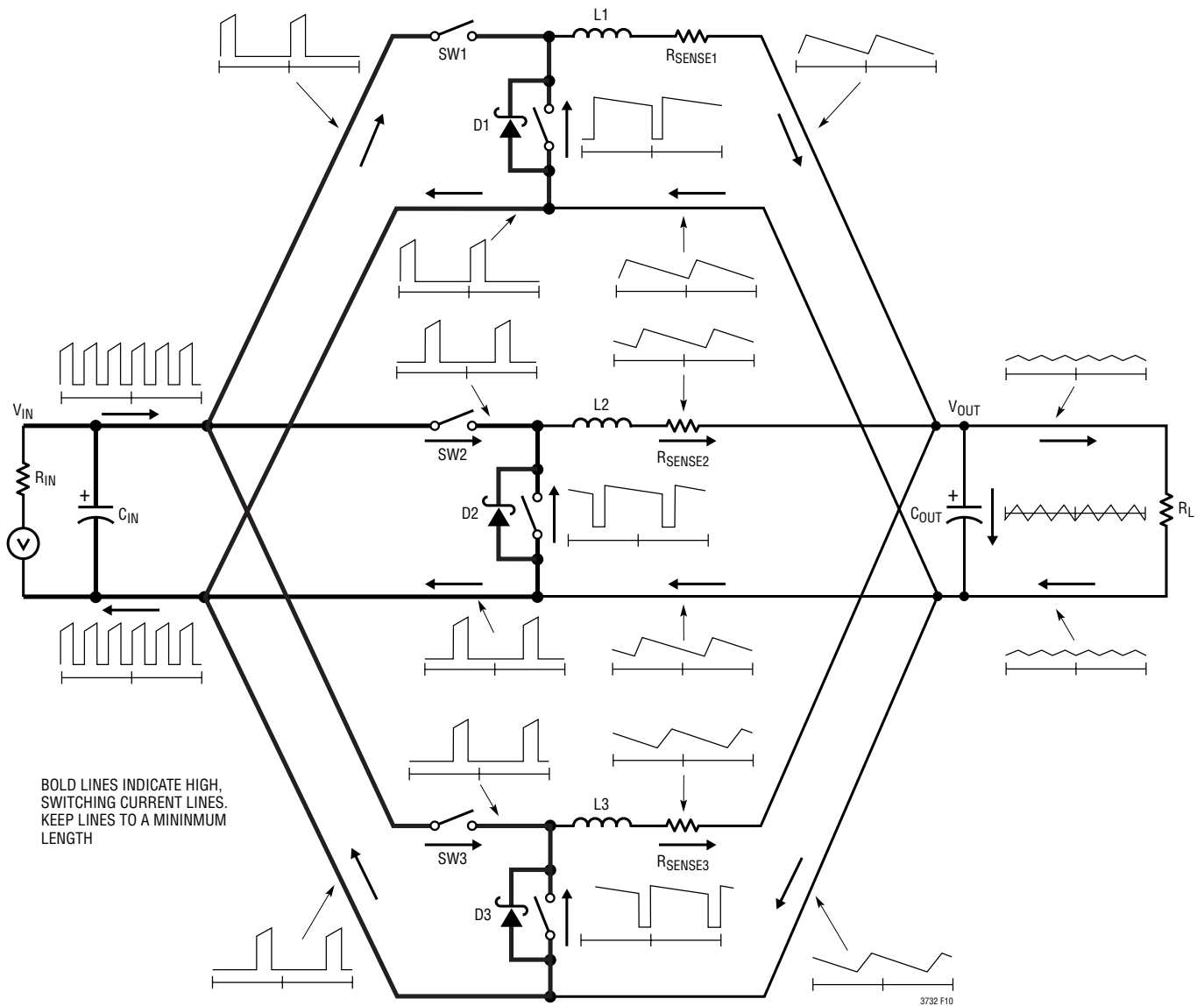
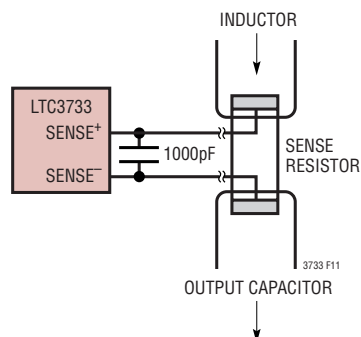


Figure 10. Branch Current Waveforms

Figure 11. Kelvin Sensing  $R_{SENSE}$

## APPLICATIONS INFORMATION

Figure 10 illustrates all branch currents in a three-phase switching regulator. It becomes very clear after studying the current waveforms why it is critical to keep the high switching current paths to a small physical size. High electric and magnetic fields will radiate from these “loops” just as radio stations transmit signals. The output capacitor ground should return to the negative terminal of the input capacitor and not share a common ground path with any switched current paths. The left half of the circuit gives rise to the “noise” generated by a switching regulator. The ground terminations of the synchronous MOSFETs and Schottky diodes should return to the bottom plate(s) of the input capacitor(s) with a short isolated PC trace since very high switched currents are present. A separate isolated path from the bottom plate(s) of the input and output capacitor(s) should be used to tie in the IC power ground pin (PGND). This technique keeps inherent signals generated by high current pulses taking alternate current paths that have

finite impedances during the total period of the switching regulator. External OPTI-LOOP compensation allows over-compensation for PC layouts which are not optimized but this is not the recommended design procedure.

### Simplified Visual Explanation of How a 3-Phase Controller Reduces Both Input and Output RMS Ripple Current

The effect of multiphase power supply design significantly reduces the amount of ripple current in both the input and output capacitors. The RMS input ripple current is divided by, and the effective ripple frequency is multiplied up by the number of phases used (assuming that the input voltage is greater than the number of phases used times the output voltage). The output ripple amplitude is also reduced by, and the effective ripple frequency is increased by the number of phases used. Figure 12 graphically illustrates the principle.

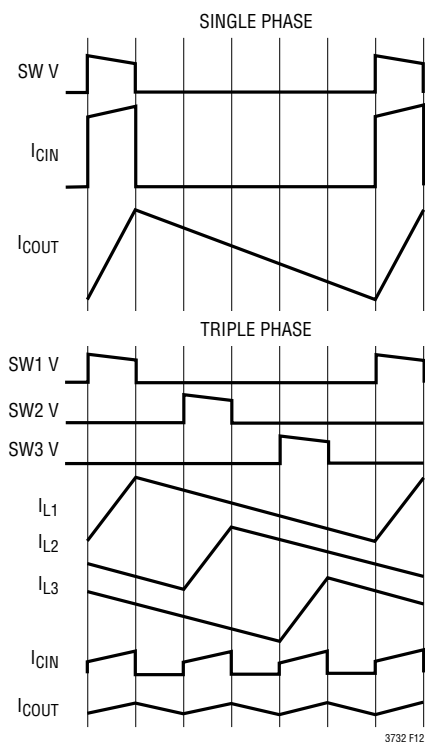


Figure 12. Single and Polyphase Current Waveforms

## APPLICATIONS INFORMATION

The worst-case input RMS ripple current for a single stage design peaks at twice the value of the output voltage. The worst-case input RMS ripple current for a two stage design results in peaks at 1/4 and 3/4 of the input voltage, and the worst-case input RMS ripple current for a three stage design results in peaks at 1/6, 1/2, and 5/6 of the input voltage. The peaks, however, are at ever decreasing levels with the addition of more phases. A higher effective duty factor results because the duty factors “add” as long as the currents in each stage are balanced. Refer to AN19 for a detailed description of how to calculate RMS current for the single stage switching regulator.

Figure 6 illustrates the RMS input current drawn from the input capacitance versus the duty cycle as determined by the ration of input and output voltage. The peak input RMS current level of the single phase system is reduced by 2/3 in a 3-phase solution due to the current splitting between the three stages.

The output ripple current is reduced significantly when compared to the single phase solution using the same inductance value because the  $V_{OUT}/L$  discharge currents term from the stages that has their bottom MOSFETs on subtract current from the  $(V_{CC} - V_{OUT})/L$  charging current resulting from the stage which has its top MOSFET on. The output ripple current for a 3-phase design is:

$$I_{P-P} = \frac{V_{OUT}}{(f)(L)}(1 - 3DC) \quad V_{IN} > 3V_{OUT}$$

The ripple frequency is also increased by three, further reducing the required output capacitance when  $V_{CC} < 3V_{OUT}$  as illustrated in Figure 4.

### Efficiency Calculation

To estimate efficiency, the DC loss terms include the input and output capacitor ESR, each MOSFET  $R_{DS(ON)}$ , inductor resistance  $R_L$ , the sense resistance  $R_{SENSE}$  and the forward drop of the Schottky rectifier at the operating output current and temperature. Typical values for the design example given previously in this data sheet are:

Main MOSFET  $R_{DS(ON)} = 7m\Omega$  (9m $\Omega$  at 90°C)

Sync MOSFET  $R_{DS(ON)} = 7m\Omega$  (9m $\Omega$  at 90°C)

$C_{INESR} = 20m\Omega$

$C_{OUTESR} = 3m\Omega$

$R_L = 2.5m\Omega$

$R_{SENSE} = 3m\Omega$

$V_{SCHOTTKY} = 0.8V$  at 15A (0.7V at 90°C)

$V_{OUT} = 1.3V$

$V_{IN} = 12V$

$I_{MAX} = 0.8V$  at 15A (0.7V at 90°C)

$\delta = 0.01\%/^{\circ}C$

$N = 3$

$f = 400kHz$

The main MOSFET is on for the duty factor  $V_{OUT}/V_{IN}$  and the synchronous MOSFET is on for the rest of the period or simply  $(1 - V_{OUT}/V_{IN})$ . Assuming the ripple current is small, the AC loss in the inductor can be made small if a good quality inductor is chosen. The average current,  $I_{OUT}$  is used to simplify the calculations. The equation below is not exact but should provide a good technique for the comparison of selected components and give a result that is within 10% to 20% of the final application.

## APPLICATIONS INFORMATION

The temperature of the MOSFET's die temperature may require iterative calculations if one is not familiar typical performance. A maximum operating junction temperature of 90° to 100°C for the MOSFETs is recommended for high reliability applications.

Common output path DC loss:

$$P_{\text{COMPAT}} \approx N \left( \frac{I_{\text{MAX}}}{N} \right)^2 (R_L + R_{\text{SENSE}}) + C_{\text{OUTESR}} \text{ Loss}$$

This totals 3.375W +  $C_{\text{OUTESR}}$  loss.

Total of all three main MOSFET's DC loss:

$$P_{\text{MAIN}} = N \left( \frac{V_{\text{OUT}}}{V_{\text{IN}}} \right) \left( \frac{I_{\text{MAX}}}{N} \right)^2 (1 + \delta) R_{\text{DS(ON)}} + C_{\text{INESR}} \text{ Loss}$$

This totals 0.83W +  $C_{\text{INESR}}$  loss.

Total of all three synchronous MOSFET's DC loss:

$$P_{\text{SYNC}} = N \left( 1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}} \right) \left( \frac{I_{\text{MAX}}}{N} \right)^2 (1 + \delta) R_{\text{DS(ON)}}$$

This totals 5.4W.

Total of all three main MOSFET's AC loss:

$$P_{\text{MAIN}} \approx 3(V_{\text{IN}})^2 \frac{45\text{A}}{(2)(3)} (2\Omega)(1000\text{pF}) \left( \frac{1}{5\text{V} - 1.8\text{V}} + \frac{1}{1.8\text{V}} \right) (400\text{kHz}) = 6.3\text{W}$$

This totals 1W at  $V_{\text{IN}} = 8\text{V}$ , 2.25W at  $V_{\text{IN}} = 12\text{V}$  and 6.25W at  $V_{\text{IN}} = 20\text{V}$ .

Total of all three synchronous MOSFET's AC loss:

$$(3)Q_G \frac{V_{\text{IN}}}{V_{\text{DSSPEC}}} (f) = (6)(15\text{nC}) \frac{V_{\text{IN}}}{V_{\text{DSSPEC}}} (4\text{E5})$$

This totals 0.08W at  $V_{\text{IN}} = 8\text{V}$ , 0.12W at  $V_{\text{IN}} = 12\text{V}$  and 0.19W at  $V_{\text{IN}} = 20\text{V}$ . The bottom MOSFET does not experience the Miller capacitance dissipation issue that the main switch does because the bottom switch turns on when its drain is close to ground.

The Schottky rectifier loss assuming 50ns nonoverlap time:

$$2 \cdot 3(0.7\text{V})(15\text{A})(50\text{ns})(4\text{E5})$$

This totals 1.26W.

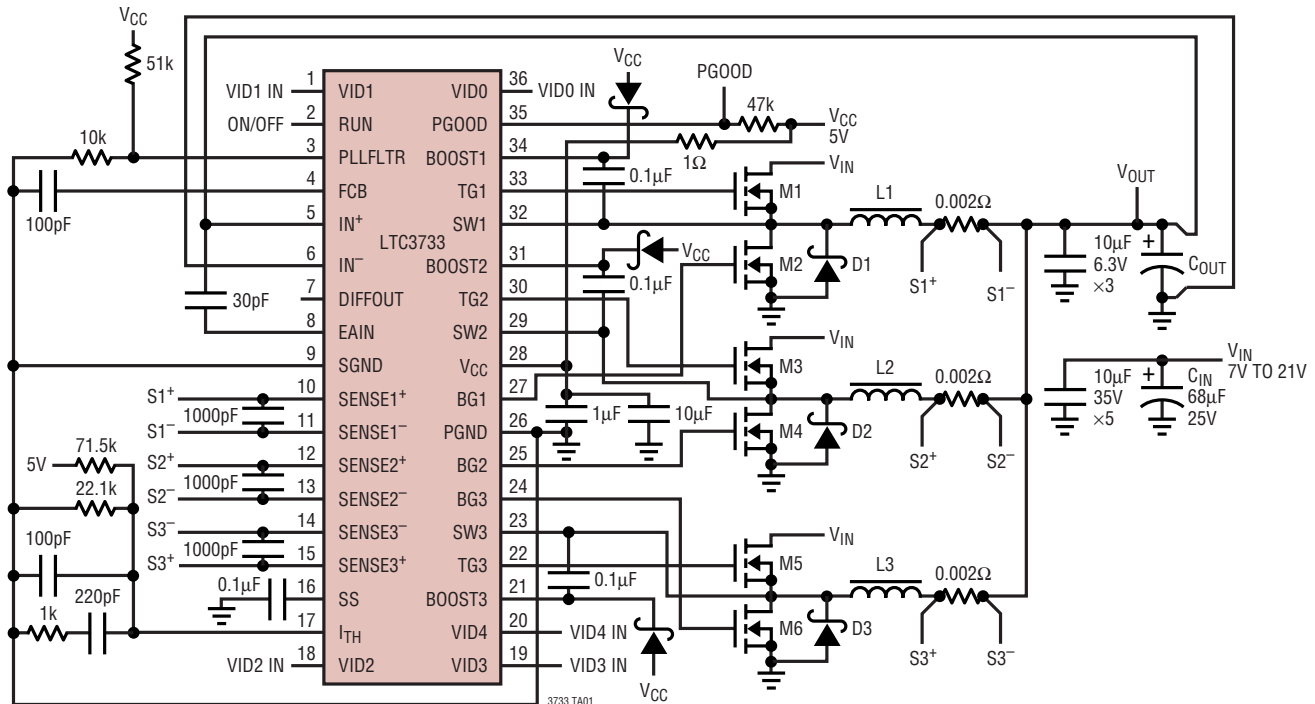
The total output power is  $(1.3\text{V})(45\text{A}) = 58.5\text{W}$  and the total input power is approximately 60W so the % loss of each component is as follows:

|                                                      |        |       |
|------------------------------------------------------|--------|-------|
| Main switch AC loss ( $V_{\text{IN}} = 12\text{V}$ ) | 2.25W  | 3.75% |
| Main switch DC loss                                  | 0.83W  | 1.4%  |
| Synchronous switch AC loss                           | 0.19W  | 0.3%  |
| Synchronous switch DC loss                           | 5.4W   | 9%    |
| Power path loss                                      | 3.375W | 5.6%  |

The numbers above represent the values at  $V_{\text{IN}} = 12\text{V}$ . It can be seen from this simple example that two things can be done to improve efficiency: 1) Use two MOSFETs on the synchronous side and 2) use a smaller MOSFET for the main switch with smaller  $C_{\text{MILLER}}$  to better balance the AC loss with the DC loss. A smaller, less expensive MOSFET can actually perform better in the task of the main switch.

## TYPICAL APPLICATION

## 65A Power Supply for AMD Opteron Processors

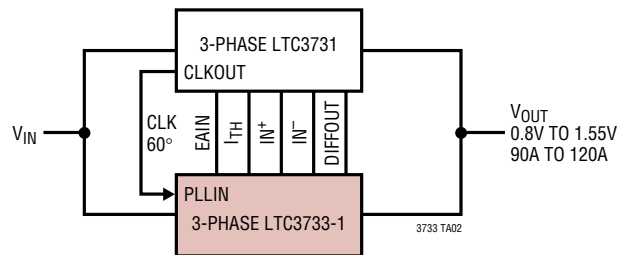


$V_{IN}$ : 7V TO 21V  
 $V_{OUT}$ : 0.8V TO 1.55V, 65A  
 SWITCHING FREQUENCY: 300kHz

$C_{IN}$ : SANYO OS-CON 25SP68M  
 $C_{OUT}$ : 330μF/2.5V × 10 SANYO POSCAP 2R5TPE330M9  
 D1 TO D3: MBRS340T3

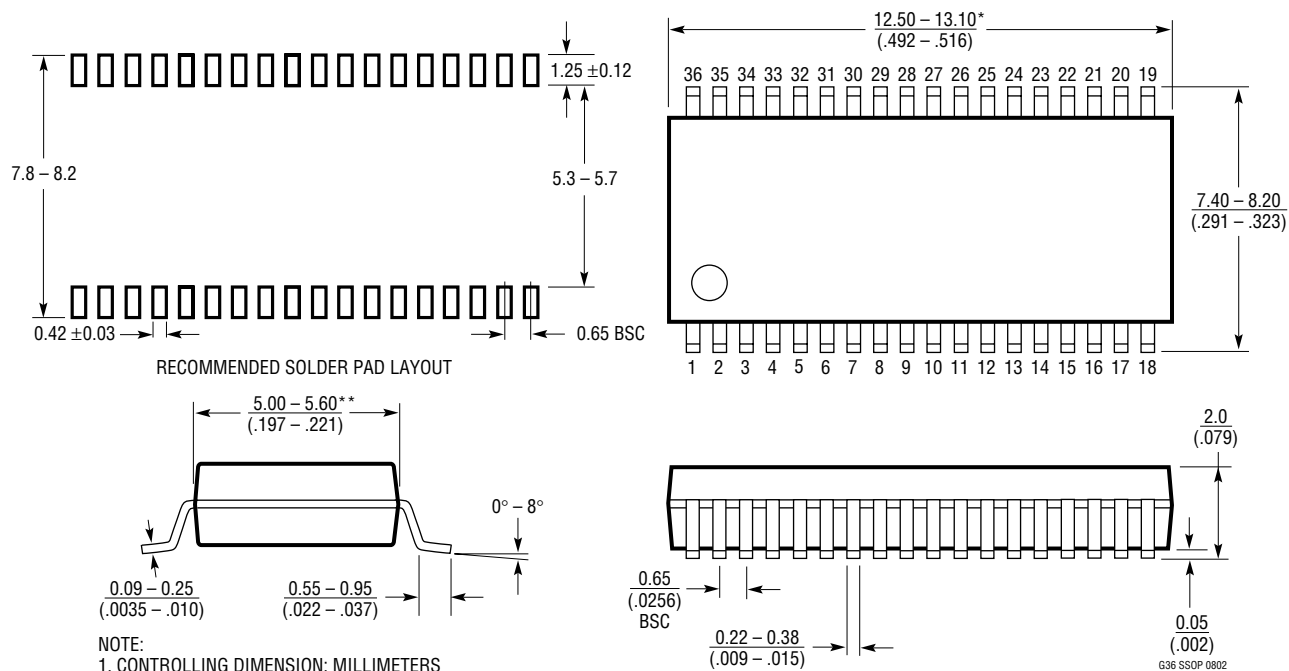
L1 TO L3: 0.68μH SUMIDA CEP125-OR6  
 M1, M3, M5: HAT2168H × 1 OR IRF7811W × 2 OR Si7860DP × 1  
 M2, M4, M6: HAT2165H × 2 OR IRF7822 × 2 OR Si7892DP × 2

## Block Diagram—6-Phase LTC3731/LTC3733-1 Supply



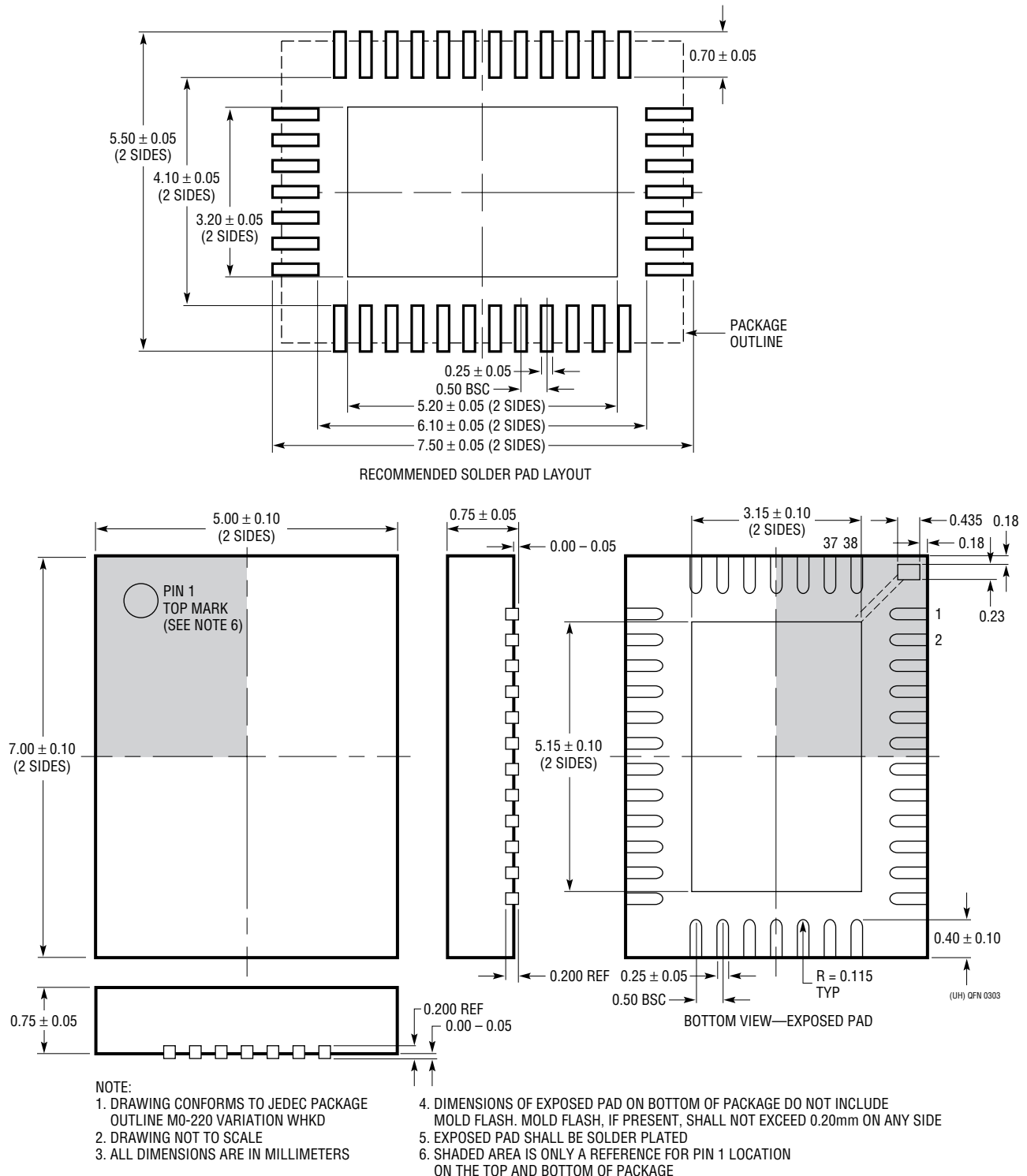
## PACKAGE DESCRIPTION

**G Package**  
**36-Lead Plastic SSOP (5.3mm)**  
 (Reference LTC DWG # 05-08-1640)



# PACKAGE DESCRIPTION

**UHF Package**  
**38-Lead Plastic QFN (7mm × 5mm)**  
 (Reference LTC DWG # 05-08-1701)



## RELATED PARTS

| PART NUMBER            | DESCRIPTION                                                                                | COMMENTS                                                                                                                                                  |
|------------------------|--------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------|
| LTC1628                | 2-Phase, Dual Output Synchronous Step-Down DC/DC Controllers                               | Reduces $C_{IN}$ and $C_{OUT}$ , Power Good Output Signal, Synchronizable, $3.5V \leq V_{IN} \leq 36V$ , $I_{OUT}$ up to 20A, $0.8V \leq V_{OUT} \leq 5V$ |
| LTC1629/<br>LTC1629-PG | 20A to 200A PolyPhase Synchronous Controllers                                              | Expandable from 2-Phase to 12-Phase, Uses All Surface Mount Components, No Heat Sink, $V_{IN}$ up to 36V                                                  |
| LTC1702                | No $R_{SENSE}^{TM}$ 2-Phase Dual Synchronous Step-Down Controller                          | 550kHz, No Sense Resistor                                                                                                                                 |
| LTC1703                | No $R_{SENSE}$ 2-Phase Dual Synchronous Step-Down Controller with 5-Bit Mobile VID Control | Mobile Pentium® III Processors, 550kHz, $V_{IN} \leq 7V$                                                                                                  |
| LTC1708-PG             | 2-Phase, Dual Synchronous Controller with Mobile VID                                       | $3.5V \leq V_{IN} \leq 36V$ , VID Sets $V_{OUT1}$ , PG00D                                                                                                 |
| LT®1709/<br>LT1709-8   | High Efficiency, 2-Phase Synchronous Step-Down Switching Regulators with 5-Bit VID         | $1.3V \leq V_{OUT} \leq 3.5V$ , Current Mode Ensures Accurate Current Sharing, $3.5V \leq V_{IN} \leq 36V$                                                |
| LTC1735                | High Efficiency Synchronous Step-Down Switching Regulator                                  | Output Fault Protection, 16-Pin SSOP                                                                                                                      |
| LTC1736                | High Efficiency Synchronous Controller with 5-Bit Mobile VID Control                       | Output Fault Protection, 24-Pin SSOP, $3.5V \leq V_{IN} \leq 36V$                                                                                         |
| LTC1778                | No $R_{SENSE}$ Current Mode Synchronous Step-Down Controller                               | Up to 97% Efficiency, $4V \leq V_{IN} \leq 36V$ , $0.8V \leq V_{OUT} \leq (0.9)(V_{IN})$ , $I_{OUT}$ up to 20A                                            |
| LTC1929/<br>LTC1929-PG | 2-Phase Synchronous Controllers                                                            | Up to 42A, Uses All Surface Mount Components, No Heat Sinks, $3.5V \leq V_{IN} \leq 36V$                                                                  |
| LTC3708                | Dual, 2-Phase, No $R_{SENSE}$ Synchronous Buck with Output Tracking                        | Up/Down Output Voltage Tracking, Track Up to 8 Supplies, Fast Transient Response                                                                          |
| LTC3711                | No $R_{SENSE}$ Current Mode Synchronous Step-Down Controller with Digital 5-Bit Interface  | Up to 97% Efficiency, Ideal for Pentium III Processors, $0.925V \leq V_{OUT} \leq 2V$ , $4V \leq V_{IN} \leq 36V$ , $I_{OUT}$ up to 20A                   |
| LTC3719                | 2-Phase, 5-Bit VID Current Mode, High Efficiency Synchronous Step-Down Controller          | AMD Hammer-K8 Processors, Wide $V_{IN}$ Range: 4V to 36V Operation                                                                                        |
| LTC3729                | 20A to 200A, 550kHz PolyPhase Synchronous Controller                                       | Expandable from 2-Phase to 12-Phase, Uses all Surface Mount Components, $V_{IN}$ up to 36V                                                                |
| LTC3731                | 3-Phase, 600kHz Synchronous Buck Switching Regulator Controller                            | Expandable from 3-Phase to 12-Phase, Uses all Surface Mount Components, $V_{IN}$ up to 36V                                                                |
| LTC3732                | 3-Phase, 5-Bit VID, 600kHz Synchronous Buck Switching Regulator Controller                 | VRM9.0 and VRM9.1 (VID = 1.1V to 1.85V)                                                                                                                   |

No  $R_{SENSE}$  is a trademark of Linear Technology Corporation. Pentium is a registered trademark of Intel Corporation.